

SCHOOL OF ELECTRONICS ENGINEERING

M. Tech Nanotechnology

(M.Tech MNT)

Curriculum

(2021-2022 admitted students)



VISION STATEMENT OF VELLORE INSTITUTE OF TECHNOLOGY

Transforming life through excellence in education and research.

MISSION STATEMENT OF VELLORE INSTITUTE OF TECHNOLOGY

World class Education: Excellence in education, grounded in ethics and critical thinking, for improvement of life.

Cutting edge Research: An innovation ecosystem to extend knowledge and solve critical problems.

Impactful People: Happy, accountable, caring and effective workforce and students.

Rewarding Co-creations: Active collaboration with national & international industries & universities for productivity and economic development.

Service to Society: Service to the region and world through knowledge and compassion.

VISION STATEMENT OF THE SCHOOL OF ELECTRONICS ENGINEERING

To be a leader by imparting in-depth knowledge in Electronics Engineering, nurturing engineers, technologists and researchers of highest competence, who would engage in sustainable development to cater the global needs of industry and society.

MISSION STATEMENT OF THE SCHOOL OF ELECTRONICS ENGINEERING

- Create and maintain an environment to excel in teaching, learning and applied research in the fields of electronics, communication engineering and allied disciplines which pioneer for sustainable growth.
- Equip our students with necessary knowledge and skills which enable them to be lifelong learners to solve practical problems and to improve the quality of human life.



M. Tech. Nanotechnology

PROGRAMME EDUCATIONAL OBJECTIVES (PEOs)

- 1. Graduates will be engineering practitioners and leaders, who would help solve industry's technological problems.
- 2. Graduates will be engineering professionals, innovators or entrepreneurs engaged in technology development, technology deployment, or engineering system implementation in industry.
- 3. Graduates will function in their profession with social awareness and responsibility.
- 4. Graduates will interact with their peers in other disciplines in industry and society and contribute to the economic growth of the country.
- 5. Graduates will be successful in pursuing higher studies in engineering or management.
- 6. Graduates will pursue career paths in teaching or research.



M. Tech Nanotechnology

PROGRAMME OUTCOMES (POs)

- PO_01: Having an ability to apply mathematics and science in engineering applications.
- PO_02: Having an ability to design a component or a product applying all the relevant standards and with realistic constraints, including public health, safety, culture, society and environment
- PO_03: Having an ability to design and conduct experiments, as well as to analyse and interpret data, and synthesis of information
- PO_04: Having an ability to use techniques, skills, resources and modern engineering and IT tools necessary for engineering practice
- PO_05: Having problem solving ability- to assess social issues (societal, health, safety, legal and cultural) and engineering problems
- PO_06: Having adaptive thinking and adaptability in relation to environmental context and sustainable development
- PO_07: Having a clear understanding of professional and ethical responsibility
- PO_08: Having a good cognitive load management skills related to project management and finance



PROGRAMME SPECIFIC OUTCOMES (PSOs)

On completion of M. Tech. (Nanotechnology) programme, graduates will be able to

PSO1: Evolving crucial understanding of Physics & Chemistry of solids, Quantum physics of nanostructures, Nano-electronics and Nano-photonics.

PSO2: Concentrating on specific skills on Synthesis of nanomaterials, thin film deposition and their characterization.

PSO3: Solve research gaps and provide solutions to socio-economic, and environmental problems.



Category-wise Credit distribution

Category	Credits
University core (UC)	27
Programme core (PC)	19
Programme elective (PE)	18
University elective (UE)	6
Bridge course (BC)	
Total credits	70



Detailed curriculum

(as given in the student curriculum view – in the order of UC, UE, PC and PE). Courses need not be listed under UE.

University Core - 27 Credits

S.	Course Code	Course Title	L	T	P	J	C
No							
1.	MAT6001	Advanced Statistical	2	0	2	0	3
		Methods					
2.	ENG5001 and	Technical English I and	{0	0	2	0	2
	ENG5002	Technical English II	0	0	2	0}	
	(or) EFL5097	(or) Foreign Language	2	0	0	0	
3.	STS5001	Soft Skills	0	0	0	0	1
4.	STS5002	Soft Skills	0	0	0	0	1
5.	SET5001	SET Project-I	0	0	0	0	2
6.	SET5002	SET Project-II	0	0	0	0	2
7.	ECE6099	Master's Thesis	0	0	0	0	16

University Elective – 6 Credits

S.No	Course Title	L	T	P	J	C
1	University Elective [#]	-	-	-	-	6

All courses offered by other M.Tech Programmes / PE of M.Tech (Nanotechnology)



Programme Core – 19 Credits

S. No	Course Code	Course Title	L	T	P	J	C
1	ECE5031	Quantum Physics for Nanostructures	2	0	0	0	2
2	ECE5032	Physics and Chemistry of Solids	2	0	0	0	2
3	ECE5033	Synthesis of Nanomaterials and Thin Film Deposition	2	0	2	4	4
4	ECE 5034	Nanomaterial Characterization Techniques	3	0	2	0	4
5	ECE 6032	Nanoelectronics	2	0	2	4	4
6	ECE 6033	Nanophotonics	3	0	0	0	3

Programme Electives - 18 Credits

S.No	Course	Course Title		T	P	J	C
	Code						
1	ECE 5035	Semiconductor Device Physics		0	0	4	3
		and Technology					
2	ECE5036	MEMS to NEMS	2	0	0	4	3
4	ECE 5037	Nanosensors	3	0	0	0	3
5	ECE 5038	Carbon Nanomaterials	3	0	0	0	3
6	ECE 5039	Lithographic Techniques for	3	0	0	0	3
		Device Fabrication					
7	ECE 5040	Plasmonics	2	0	0	4	3
8	ECE 6031	Nanomagnetism- Fundamentals	3	0	0	0	3
		and Applications					
9	ECE 6034	Energy Technologies	3	0	0	0	3
10	ECE 6035	Spintronics	2	0	0	4	3
11	ECE6039	Nanoelectronic Circuit Design	3	0	0	0	3
12	ECE6095	Quantum Computation and	3	0	0	0	3
		Communication Technologies					



Syllabus



Course Code	Course Title	L T PJ C
MAT6001	ADVANCED STATISTICAL METHODS	2 0 2 0 3
Pre-requisite	nil	Syllabus version
		2.0
Course Objective	s:	

- 1. To provide students with a framework that will help them choose the appropriate descriptive statistics in various data analysis situations.
- 2. To analyse distributions and relationships of real-time data.
- 3. To apply estimation and testing methods to make inference and modelling techniques for decision making using various techniques including multivariate analysis.

Expected Course Outcome:

- 1. Understand the value of statistics as a discipline and its relevance for Engineering
- 2. Analyze data using appropriate graphical methods and numerical summaries
- 3. Interpret and communicate the outcomes of estimation and hypothesis tests in the context of a problem
- 4. Perform large sample test and small sample testing of Hypothesis as well as calculate confidence interval for a population parameter for real time data.
- 5. describe and verify mathematical considerations for analyzing time series, including concepts of white noise, stationarity, auto-covariance, autocorrelation; apply various techniques of time series models, including the regression with ARMA models

Module:1 Basic Statistical Tools for Analysis: 4 hours

Summary Statistics, Correlation and Regression, Concept of R² and Adjusted R² and and Partial and

Multiple Correlation, Fitting of simple and Multiple Linear regression, Explanation and Assumptions of Regression Diagnostics

Module:2 Statistical inference: 9 hours

Basic Concepts, Normal distribution-Area properties, Steps in tests of significance –large sample tests-Z tests for Means and Proportions, Small sample tests –t-test for Means, F test for Equality of Variances, Chi-square test for independence of Attributes.

Module:3 Modelling and Forecasting Methods: 9 hours

Introduction: Concept of Linear and Non Liner Forecasting model ,Concepts of Trend, Exponential Smoothing, Linear and Compound Growth model, Fitting of Logistic curve and their Applications, Moving Averages, Forecasting accuracy tests.

Probability models for time series: Concepts of AR, ARMA and ARIMA models.

Module:4	Design of Experiments:	6 hours
	variance – one and two way classifications – Principle of design of D, Concepts of 22 and 23 factorial experiments	f experiments, CRD –
Module:5	Contemporary issues:	2 hours



Lec	ture by Industry Experts			
Tot	al Lecture hours:	30 hours		
100	an Beeture nours.	o nour		
	t Book(s)			
	Applied Statistics and Probability for Engineers, 6ed, (2016),Douglas C. Mor C. Runger, John Wiley & Sons	ntgomery George		
	Time Series Analysis and Its Applications With R Examples (2017), by Shun Stoffer, David S. Springer publications	nway, Robert H.,		
	erence Books	0 1517		
	The Elements of Statistical Learning: Data Mining, Inference, and Prediction (Springer Series in Statistics)(2017), by Trevor Hastie and Robert Tibshirani			
2	Introduction to Probability and Statistics: Principles and Applications for Eng Computing Sciences(2017), Mc.Grawhill education by J. Susan Milton and Jo			
Mo	de of Evaluation			
	Digital Assignments, Quiz, Continuous Assessments, Final Assessment	nt Test		
	of Challenging Experiments (Indicative)	2.1		
1.	Computing Summary Statistics using real time data	2 hours		
2	plotting and visualizing data using Tabulation and Graphical Representations.			
Applying simple linear and multiple linear regression models to real dataset; computing and interpreting the coefficient of determination for scale data.				
4.	Testing of hypothesis for Large sample tests for real-time problems.	2 hours		
5.	5. Testing of hypothesis for Small sample tests for One and Two Sample mean and paired comparison (Pre-test and Post-test)			
6.	Testing of hypothesis for Small Sample tests for F-test	2 hours		
7	Testing of hypothesis for Small Sample tests for Chi-square test	2 hours		
8	Applying Time series analysis-Trends. Growth ,Logistic, Exponential mode	els 2 hours		
9 Applying Time series model AR ,ARMA and ARIMA and testing Forecasting accuracy tests.				
10	Performing ANOVA (one-way and two-way), CRD, RBD and LSD for real dataset.	2 hours		
Performing 22 factorial experiments with real time Applications				
12	Performing 23 factorial experiments with real time Applications	2 hours		



		Tota	al Laboratory Hours	24 hours		
Mode of Evaluation						
Weekly Assessments, Final Assessment Test						
Recommended by Board of Studies 11-08-2017						
Approved by Academic Council	No.46	Date	24-08-17			



Course co	ode	Course title	L T P J C
ENG5001		Fundamentals of Communication Skills	0 0 2 0 1
Pre-requi	site	Not cleared EPT (English Proficiency Test)	Syllabus version
			1.0
Course O			
1. To enab	le learne	ers learn basic communication skills - Listening, Speaking, Re	ading and Writing
-		apply effective communication in social and academic context	
3. To mak	e student	s comprehend complex English language through listening ar	nd reading
Expected	Course	Outcome:	
1. Enhance	e the liste	ening and comprehending skills of the learners	
2.Acquire	speaking	g skills to express their thoughts freely and fluently	
3.Learn str	rategies f	For effective reading	
4.Write gr	ammatic	al correct sentences in general and academic writing	
5. Develop	technic technic	al writing skills like writing instructions, transcoding etc.,	
Module:1	Listen	ing	8 hours
Understan			•
Listening t			
		fic Information	
Module:2	Speak	ing	4 hours
Exchangin			
		es, Events and Quantity	
Module:3			6 hours
Identifying			
Inferring N			
Interpretin			
		ng: Sentence	8hours
Basic Sent	tence Str	ucture	•
Connectiv	es		
Transform	ation of	Sentences	
Synthesis	of Senter	nces	
Module:5	Writin	ng: Discourse	4hours
Instruction	ıs	-	<u>.</u>
Paragraph			
Transcodi	ng		
			201-
Total Lec	ture hou	ırs:	30 hour
Text Book	K(S)		
1. Redst Intern		ris, Theresa Clementson, and Gillie Cunningham. Factudent's Book. 2013, Cambridge University Press.	ce2face Upper
Reference		, <u>Gr</u> - rr ry	
		.Stepping Stones: A guided approach to writing sentences and	d Paragraphs
		on), 2012, Library of Congress.	
		nitcomb & Leslie E Whitcomb, Effective Interpersonal and Te	am
		on Chille for Engineers 2012 John Wiley & Song Ing. Hohel	

Communication Skills for Engineers, 2013, John Wiley & Sons, Inc., Hoboken: New Jersey.



2	A D-4:1 II1- E::1 0.E	D1441	NT N <i>I</i> I1	:- Ci	
3.	ArunPatil, Henk Eijkman & Engineers and IT Professionals 20				ation Skills for
4.	Engineers and IT Professionals,20 Judi Brownell, Listening: Attitude				outledge:USA
5.	John Langan, Ten Steps to Impro				
$ $ $^{\circ}$.	Press:USA	vilig College Rea	unig Skin	s, 2014, 0 Eu	ition, Townsend
6.	Redston, Chris, Theresa Clements	on, and Gillie Cu	nningham.	Face2face Up	per Intermediate
0.	Teacher's Book. 2013, Cambridge		6		
	,	•			
	Authors, book title, year of publication	ation, edition num	ber, press,	place	
Mod	de of Evaluation: CAT / Assignmen	nt / Quiz / FAT / P	roject / Se	minar	
List	of Challenging Experiments (Ind	licative)			
1.	Familiarizing students to adjective		orming ad	jectives with	2 hours
	all letters of the English alphabet	and asking them to	o add an a	djective that	
	starts with the first letter of their r	name as a prefix.			
2.	Making students identify their peo	er who lack Pace,	Clarity and	d Volume	4 hours
	during presentation and respond u		- · · · · · · · · · · · · · · · · · · ·		
3.	Using Picture as a tool to enhance	e learners speaking	g and writi	ng skills	2 hours
4.	Using Music and Songs as tools	to enhance pronun	ciation in	the target	2 hours
	language / Activities through VIT	Community Radi	0		
5.	Making students upload their Self	f- introduction vid	eos in Vin	neo.com	4 hours
6.	Brainstorming idiomatic expression	ons and making th	em use the	ose in to their	4 hours
	writings and day to day conversat				
7.	Making students Narrate events b	•		· ·	4 hours
	add flavor to their language / Acti				
8	Identifying the root cause of stage	e fear in learners a	nd providi	ng remedies	4 hours
0	to make their presentation better			4:	2 1
9	Identifying common Spelling & S day to day conversations	entence errors in	Letter wri	ting and other	2 hours
10.	Discussing FAQ's in interviews v	with answers so the	at the learn	ner gets a	2 hours
10.	better insight in to interviews / Ac			•	2 110013
	better misight in to interviews / / K	tivities through v	TI Commi	unity Radio	
			Total F	ractical Hours	30 hours
	le of evaluation: Online Quizzes, P.	resentation, Role 1	olay, Grou	p Discussions,	Assignments,
	i Project	22-07-2017			
	ommended by Board of Studies oroved by Academic Council	No. 46	Date	24-8-2017	
App	noved by Academic Council	110. 40	Date	24-0-201 <i>1</i>	



Course code		Course title	L T P J C
ENG5002	Pro	ofessional and Communication Skills	s 0 0 2 0 1
Pre-requisit	e ENG5001		Syllabus version
C Ol.:			1.3
Course Obj		ffeetive Language and Communication	Clrilla
		effective Language and Communicatio and Professional skills	on Skins
		and Froiessional skins an active digital footprint	
3. 10 equip (ne students to create a	an active digital footprint	
Expected C	ourse Outcome:		
	inter-personal commu	unication skills	
	problem solving and		
3. Learn the	styles and mechanic	es of writing research reports	
		ng and presentation skills	
5. Apply th	e acquired skills and o	excel in a professional environment	
Module:1	Personal Interaction	on	2hours
	Oneself- one's career		211001
indoddenig '	one s career	gouis	
Activity: SW	OT Analysis		
Module:2	Interpersonal Inte	praction	2 hour
		h the team leader and colleagues at the	
-	e Plays/Mime/Skit		r
Module:3	Social Interaction		2 hours
Use of Socia	Media, Social Netwo	orking, gender challenges	-
	ating LinkedIn profil		
Module:4	Résumé Writing		4 hour
	8	1 111	4 Hours
, ,	b requirement and ke	•	
Activity: Pre	pare an Electronic Ré	ésumé	
Module:5	Interview Skills		4 hour
Placement/Jo	bb Interview, Group I	Discussions	
	ck Interview and mod		
Module:6	Report Writing		4 hour
Language an	d Mechanics of Writi	ing	
Activity: Wr	iting a Report		
Module:7	Study Skills: Note	making	2hour
C	the report		-
Summarizin	; the report		



Modul	le:8	Interpreting skills	2 hours					
Interpr	et data	in tables and graphs						
Activit	ty: Trar	nscoding						
Modul	le:9	Presentation Skills	4 hours					
Oral P	resenta	tion using Digital Tools						
Activit	tv: Oral	presentation on the given topic using appropriate non-verbal cues						
Activit	ty. Ora	presentation on the given topic using appropriate non-verbar cues						
Madul	10.10	Ducklana Calada a Chilla	4 h anna					
Modul	ie:10	Problem Solving Skills	4 hours					
Proble	m Solv	ing & Conflict Resolution						
Activit	tv· Case	e Analysis of a Challenging Scenario						
7101111	ty. Cast	7 mary 515 of a Chancing ing Sechario	30hours					
		Total Lecture hours:						
Text B	Book(s)							
		gar Nitin and Mamta Bhatnagar, Communicative English For Enginee onals, 2010, Dorling Kindersley (India) Pvt. Ltd.	ers And					
	ence Bo							
		kman and Christopher Turk, Effective Writing: Improving Scientific, s Communication, 2015, Routledge	Technical and					
		Bairaktarova and Michele Eodice, Creative Ways of Knowing in Engranternational Publishing	gineering, 2017,					
		A Whitcomb & Leslie E Whitcomb, Effective Interpersonal Control of the Control of						
	ArunPatil, Henk Eijkman &Ena Bhattacharya, New Media Communication Skills for Engineers and IT Professionals,2012, IGI Global, Hershey PA.							
Mode	of Eval	uation: CAT / Assignment / Quiz / FAT / Project / Seminar						
List of	f Chall	enging Experiments (Indicative)						
1. S		Analysis – Focus specially on describing two strengths and two	2 hours					
2. F	Role Pla	ays/Mime/Skit Workplace Situations	4 hours					
		Social Media – Create a LinkedIn Profile and also write a page or areas of interest	2 hours					
4. F	Prepare	an Electronic Résumé and upload the same in vimeo	2 hours					
5.	Group c	liscussion on latest topics	4 hours					
		Writing – Real-time reports	2 hours					
	Writing articles	an Abstract, Executive Summary on short scientific or research	4 hours					



8	2 hours							
9	bal cues	4 hours						
10	10 Problem Solving Case Analysis of a Challenging Scenario							
			Total Lab	oratory Hours	30 hours			
Mod	Mode of evaluation: : Online Quizzes, Presentation, Role play, Group Discussions, Assignments,							
Mini	Project							
Reco	ommended by Board of Studies	22-07-2017						
Appı	roved by Academic Council	No. 47	Date	05-10-2017				



Course code	Course Title	L T P J C
GER5001	Deutsch für Anfänger	2 0 0 0 2
Pre-requisite	NIL	Syllabus version
		v.1

The course gives students the necessary background to:

- 1. enable students to read and communicate in German in their day to day life
- 2. become industry-ready
- 3. make them understand the usage of grammar in the German Language.

Expected Course Outcome:

The students will be able to

- 1.create the basics of German language in their day to day life.
- 2.understand the conjugation of different forms of regular/irregular verbs.
- 3.understand the rule to identify the gender of the Nouns and apply articles appropriately.
- 4.apply the German language skill in writing corresponding letters, E-Mails etc.
- 5.create the talent of translating passages from English-German and vice versa and To frame simple dialogues based on given situations.

Module:1 3 hours

Einleitung, Begrüssungsformen, Landeskunde, Alphabet, Personalpronomen, Verb Konjugation, Zahlen (1-100), W-fragen, Aussagesätze, Nomen – Singular und Plural

Lernziel:

Elementares Verständnis von Deutsch, Genus- Artikelwörter

Module:2 3 hours

Konjugation der Verben (regelmässig /unregelmässig) die Monate, die Wochentage, Hobbys, Berufe, Jahreszeiten, Artikel, Zahlen (Hundert bis eine Million), Ja-/Nein- Frage, Imperativ mit Sie

Lernziel:

Sätze schreiben, über Hobbys erzählen, über Berufe sprechen usw.

Module:3 4 hours

Possessivpronomen, Negation, Kasus- AkkusatitvundDativ (bestimmter, unbestimmterArtikel), trennnbare verben, Modalverben, Adjektive, Uhrzeit, Präpositionen, Mahlzeiten, Lebensmittel, Getränke

Lernziel:

Sätze mit Modalverben, Verwendung von Artikel, über Länder und Sprachen sprechen, über eine Wohnung beschreiben.

Module:4 6 hours

Übersetzungen: (Deutsch – Englisch / Englisch – Deutsch)

Lernziel:

Grammatik – Wortschatz – Übung

Module:5 5 hours

Leseverständnis, Mindmap machen, Korrespondenz- Briefe, Postkarten, E-Mail

Lernziel:



W	ortschatzbildung und aktiver Sprach	gebrauch			
***	rtschatzondung und aktiver Sprach	georauen			
Mo	odule:6 .				3 hours
	fsätze :				
Me	ine Universität, Das Essen, mein Fr	eund oder meine F	reundin, n	neine Familie, ei	n Fest in
	utschland usw		ŕ	,	
Mo	dule:7				4 hours
Dia	lloge:				
	a) Gespräche mit Familienmitglied	dern, Am Bahnhof	•		
	b) Gespräche beim Einkaufen; in	einem Supermarkt	; in einer	Buchhandlung;	
	c) in einem Hotel - an der Rezepti	on ;ein Termin be	im Arzt.		
Tre	ffen im Cafe				
Mo	dule:8				2 hours
Gu	est Lectures/Native Speakers / Fei	nheiten der deutsc	chen Sprac	che, Basisinform	nation über die
det	tschsprachigen Länder				
			Total L	ecture hours:	30 hours
Te	xt Book(s)				
1.	Studio d A1 Deutsch als Fren	ndsprache, Hern	nann Fun	k, Christina K	Kuhn, Silke
	Demme : 2012				
-	ference Books				
1	Netzwerk Deutsch als Fremdsprac	he A1, Stefanie De	engler, Pau	ıl Rusch, Helen	Schmtiz, Tanja
	Sieber, 2013	3.6411	Q	012	
2	Lagune ,Hartmut Aufderstrasse, J				
3	Deutsche Sprachlehrefür AUslände				3.411 1
4	ThemenAktuell 1, HartmurtAufde Helmut Müller, 2010	rstrasse, Heiko Bo	ck, Mechu	niiaGeraes, Jutta	Muller und
	*				
	www.goethe.de wirtschaftsdeutsch.de				
	hueber.de				
	klett-sprachen.de				
1 / I	www.deutschtraning.org	ot / Ovia / Caraina and	/ EAT		
	de of Evaluation: CAT / Assignmen	04-03-2016	/ FAI		
	commended by Board of Studies proved by Academic Council	41	Date	17-06-2016	
Αþ	proved by Academic Council	71	Date	17-00-2010	



Course code	Course Title	L T P J C
FRE5001	FRANCAIS FONCTIONNEL	2 0 0 0 2
Pre-requisite	Nil	Syllabus version
		1.0

The course gives students the necessary background to:

- 1. demonstrate competence in reading, writing, and speaking basic French, including knowledge of vocabulary (related to profession, emotions, food, workplace, sports/hobbies, classroom and family).
- 2. achieve proficiency in French culture oriented view point.

Expected Course Outcome:

The students will be able to

- 1. remember the daily life communicative situations via personal pronouns, emphatic pronouns, salutations, negations, interrogations etc.
- 2. create communicative skill effectively in French language via regular / irregular verbs.
- 3. demonstrate comprehension of the spoken / written language in translating simple sentences.
- 4. understand and demonstrate the comprehension of some particular new range of unseen written materials.
- 5. demonstrate a clear understanding of the French culture through the language studied.

Module:1 Saluer, Se présenter, Etablir des contacts 3 hours Les Salutations, Les nombres (1-100), Les jours de la semaine, Les mois de l'année, Les Pronoms Sujets, Les Pronoms Toniques, La conjugaison des verbes réguliers, La conjugaison des verbes

Sujets, Les Pronoms Toniques, La conjugaison des verbes réguliers, La conjugaison des verbes irréguliers- avoir / être / aller / venir / faire etc.

Module:2	Présenter que des nouvelles de	3 hours							
La c	conjugaison	des	verbes	Pronominaux,	La	Négation,			
L'interroga	L'interrogation avec 'Est-ce que ou sans Est-ce que'.								

Module:3 Situer un objet ou un lieu, Poser des questions 4 hours

L'article (défini/ indéfini), Les prépositions (à/en/au/aux/sur/dans/avec etc.), L'article contracté, Les heures en français, La Nationalité du Pays, L'adjectif (La Couleur, l'adjectif possessif, l'adjectif démonstratif/ l'adjectif interrogatif (quel/quelles/quelle/quelles), L'accord des adjectifs avec le nom, L'interrogation avec Comment/ Combien / Où etc.,

Module:4	Faire de	s achats,	Comprendre	un	texte	court,	Demander	et	6 hours
	indiquer l	le chemin.							
La traductio	n cimple :	français an	alais / analais	franc	onic)				

La traduction simple :(français-anglais / anglais –français)

Module:5	Trouver les questions, Répondre aux questions générales en	5 hours
	français.	

L'article Partitif, Mettez les phrases aux pluriels, Faites une phrase avec les mots donnés, Exprimez les phrases données au Masculin ou Féminin, Associez les phrases.



Mo	dule:6	Comment ecrire un pass	age			3 hours
Déc	crivez :					
La	Famille /	La Maison, /L'université /I	Les Loisirs/ La Vi	ie quotidier	nne etc.	
					_	
Mo	dule:7	Comment ecrire un dialo	ogue			4 hours
	logue:					
		erver un billet de train				
		e deux amis qui se rencontr				
	,	ni les membres de la famille	e			
	g) Ent	re le client et le médecin				
					T	
Mo	dule:8	Invited Talk: Native spo	eakers			2 hours
						•
				Tota	al Lecture hours:	30 hours
	t Book(D 1111	CI E I	D : 2010
1.		, Méthode de français, J. G				
2		, Cahier d'exercices, J. Gira	ardet, J. Pecheur,	Publisher (LE International, P	arıs 2010.
	erence l		' D/' M/		T T T	D. 1.
1.		EXIONS 1, Méthode de fra	ınçais, Regine Me	erieux, Y ve	s Loiseau,Les Editio	ons Didier,
	2004.					
2	COMN	IEXIONS 1, Le cahier d'ex	ansiana Dánina N	Mániana Va	vas Laisaass. Las Édi	:4: a.m.s
2		*	ercices, Regine iv	ierieux, i v	es Loiseau, Les Eu	luons
	Didier,	2004.				
3	AI TE	R EGO 1, Méthode de franc	cais Annia Rarth	et Cathorir	ne Hugo Váronique	M
3		n, Béatrix Sampsonis, Mon	•		•	· 1V1.
	Kiziiia	n, beautx Sampsoms, Mon	ique waendendri	es, machet	te iivie 2000.	
Mo	de of Ev	aluation: CAT / Assignmen	nt / Ouiz / Semina	r / FAT		
		ded by Board of Studies	26.02.2016	·		
		y Academic Council	No.41	Date	17-06-2016	
11	-	-				



Course code	Course Title		L	T	P	J	С
SET 5001	SCIENCE, ENGINEERING AND TECHNOLOGY PROJECT- I		0	0	0	0	2
Pre-requisite		Syllabus Version				n	
Anti-requisite]	1.10

- To provide opportunity to involve in research related to science / engineering
- To inculcate research culture
- To enhance the rational and innovative thinking capabilities

Expected Course Outcome:

On completion of this course, the student should be able to:

- 1. Identify problems that have relevance to societal / industrial needs
- 2. Exhibit independent thinking and analysis skills
- 3. Demonstrate the application of relevant science / engineering principles

Modalities / Requirements

- 1. Individual or group projects can be taken up
- 2. Involve in literature survey in the chosen field
- 3. Use Science/Engineering principles to solve identified issues
- 4. Adopt relevant and well-defined / innovative methodologies to fulfill the specified objective
- 5. Submission of scientific report in a specified format (after plagiarism check)

Student Assessment: Periodical reviews, oral/poster presentation						
Recommended by Board of Studies	17-08-2017					
Approved by Academic Council	No. 47	Date	05-10-2017			



SET 5002 SCIENCE, ENGINEERING AND TECHNOLOGY PROJECT- II	_				
IROSECT	0	0	0	0	2
Pre-requisite Syll	labu	ıs '	Vei	sic	n
Anti-requisite					1.10

- 1. To provide opportunity to involve in research related to science / engineering
- 2. To inculcate research culture
- 3. To enhance the rational and innovative thinking capabilities

Expected Course Outcome:

On completion of this course, the student should be able to:

- 1. Identify problems that have relevance to societal / industrial needs
- 2. Exhibit independent thinking and analysis skills
- 3. Demonstrate the application of relevant science / engineering principles

Modalities / Requirements

- 1. Individual or group projects can be taken up
- 2. Involve in literature survey in the chosen field
- 3. Use Science/Engineering principles to solve identified issues
- 4. Adopt relevant and well-defined / innovative methodologies to fulfill the specified objective
- 5. Submission of scientific report in a specified format (after plagiarism check)

3. Submission of scientific report in a specified format (after pragramsin check)								
Student Assessment: Periodical review	Student Assessment: Periodical reviews, oral/poster presentation							
Recommended by Board of Studies	17-08-2017							
Approved by Academic Council	No. 47	Date	05-10-2017					



Course cod	le	Course title	L T P J C
STS 5001		Essentials of Business Etiquette and problem solving	3 0 0 0 1
Pre-requisi	ite	None	Syllabus version
Course Ob	iectives		
		the students' logical thinking skills	
		e strategies of solving quantitative ability problems	
		ne verbal ability of the students	
		critical thinking and innovative skills	
		6	
Expected C	Course	Outcome:	
		idents to use relevant aptitude and appropriate language to exp	ress themselves
		icate the message to the target audience clearly	
		s will be able to be proficient in solving quantitative aptitude a	and verbal ability
		Evarious examinations effortlessly	•
		·	
Module:1	Busin	ess Etiquette: Social and Cultural Etiquette and Writing	9 hours
	Comp	oany Blogs and Internal Communications and Planning and	1
	_	ng press release and meeting notes	
	***************************************	ing press release and meeting notes	
Value, Man	ners, C	ustoms, Language, Tradition, Building a blog, Developing brai	nd message,
		Competition, Open and objective Communication, Two way di	
Understand	ing the	audience, Identifying, Gathering Information, Analysis, Deterr	nining, selecting
plan, Progre	ess chec	k, Types of planning, Write a short, catchy headline, Get to the	e Point –
summarize	your su	bject in the first paragraph., Body – Make it relevant to your at	idience,
M112	C4 J	-1-11- T	2 h
Module:2	Study	skills – Time management skills	3 hours
Prioritizatio	n. Proc	rastination, Scheduling, Multitasking, Monitoring, working ur	nder pressure and
adhering to			rati prossure and
Module:3	Prese	ntation skills – Preparing presentation and Organizing	7 hours
	mater	ials and Maintaining and preparing visual aids and Dealin	g
		questions	
	,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,	1400110110	
10 Tips to p	repare	PowerPoint presentation, Outlining the content, Passing the El	evator Test, Blue
sky thinkin	ig, Intr	oduction, body and conclusion, Use of Font, Use of	Color, Strategic
presentation	i, Impoi	tance and types of visual aids, Animation to captivate your au-	dience, Design of
posters, Se	tting o	at the ground rules, Dealing with interruptions, Staying is	n control of the
questions, H	Handling	g difficult questions	
Module:4	_	titative Ability -L1 – Number properties and Averages and	11 hours
	Progr	essions and Percentages and Ratios	

Number of factors, Factorials, Remainder Theorem, Unit digit position, Tens digit position, Averages, Weighted Average, Arithmetic Progression, Geometric Progression, Harmonic Progression, Increase & Decrease or successive increase, Types of ratios and proportions



Mo	dule:5	Reasoning Ability-L1 – Analytical Reasoning	8 hours			
		gement (Linear and circular & Cross Variable Relationship), Blood Relationship, Blood Relationship, Puzzle test, Selection Decision table	ons,			
Mo	dule:6	Verbal Ability-L1 – Vocabulary Building	7 hours			
-	-	& Antonyms, One-word substitutes, Word Pairs, Spellings, Idioms, Senten, Analogies	ence			
		Total Lecture hours:	45 hours			
Re	ference l	Books				
1.	Tools f	Patterson, Joseph Grenny, Ron McMillan, Al Switzler (2001) Crucial Confor Talking When Stakes are High. Bangalore. McGraw-Hill Contemporary	ry			
2.	Books	Carnegie, (1936) How to Win Friends and Influence People. New York	rk. Gallery			
3.	Scott P	eck. M (1978) Road Less Travelled. New York City. M. Scott Peck.				
4.	FACE (2016) Aptipedia Aptitude Encyclopedia. Delhi. Wiley publications					
5.	ETHN	US (2013) Aptimithra. Bangalore. McGraw-Hill Education Pvt. Ltd.				
We	ebsites:					
1.	www.c	halkstreet.com				
2.	www.s	killsyouneed.com				
3.	www.n	nindtools.com				
4.	www.t	nebalance.com				
5.		guru.000				
		valuation: FAT, Assignments, Projects, Case studies, Role plays, nts with Term End FAT (Computer Based Test)				



Course ande	Course title	TT	D 1				
Course code STS 5002		1 T T 3 0	P J 0	_			
	Preparing for Industry None S						
Pre-requisite	None	Syllabu:	s ver	SIOII			
Course Objectives:	 To challenge students to explore their problem-solving To develop essential skills to tackle advance quantitati ability questions To have working knowledge of communicating in Eng 	ve and	verb	al			
Expected Course Outcome:	 Enabling students to simplify, evaluate, analyze and us expressions to simulate real situations to be industry re The students will be able to interact confidently and use do models effectively The students will be able to be proficient in solving quaptitude and verbal ability questions of various examine effortlessly 	eady. ecision r iantitati	makir				
Module:1	Interview skills – Types of interview and Techniques to face remote interviews and Mock Interview		3 h	ours			
Structured and unstructured interview orientation, Closed questions and hypothetical questions, Interviewers' perspective, Questions to ask/not ask during an interview, Video interview, Recorded feedback, Phone interview preparation, Tips to customize preparation for personal interview, Practice rounds							
Module:2	Resume skills – Resume Template and Use of power verbs and Types of resume and Customizing resume		2 h	ours			
Quiz on types of	dard resume, Content, color, font, Introduction to Power verb resume, Frequent mistakes in customizing resume, Layout - requirement, Digitizing career portfolio			1 '			
Module:3	Emotional Intelligence - L1 – Transactional Analysis and Brain storming and Psychometric Analysis and Rebus Puzzles/Problem Solving		12 h	ours			
Brainstorming, Step brainstorming, Sta	Introduction, Contracting, ego states, Life positions, Individual Brainstorming, Group Brainstorming, Stepladder Technique, Brain writing, Crawford's Slip writing approach, Reverse brainstorming, Star bursting, Charlette procedure, Round robin brainstorming, Skill Test, Personality Test, More than one answer, Unique ways						
Madal 4	O		141				
Module:4	Quantitative Ability-L3 – Permutation-Combinations and Probability and Geometry and mensuration and Trigonometry and Logarithms and Functions and Quadratic Equations and Set Theory		14 h	ours			
	ig, Linear Arrangement, Circular Arrangements, Condition			-			

Independent and Dependent Events, Properties of Polygon, 2D & 3D Figures, Area & Volumes, Heights and distances, Simple trigonometric functions, Introduction to logarithms, Basic rules of



logarithms, Intro	oduction to functions, Basic rules of functions, Understand	ding Quadratic				
Equations, Rules	& probabilities of Quadratic Equations, Basic concepts of Venn D	iagram				
Module:5	Reasoning ability-L3 – Logical reasoning and Data Analysis and Interpretation	7 hours				
	ry logic, Sequential output tracing, Crypto arithmetic, Data Sufficivanced, Interpretation tables, pie charts & bar chats	ency, Data				
Module:6	Verbal Ability-L3 – Comprehension and Logic	7 hours				
•	nension, Para Jumbles, Critical Reasoning (a) Premise and Conclus ference, (c) Strengthening & Weakening an Argument	sion, (b)				
Total Lecture ho	ours:	45 hours				
References	 Michael Farra and JIST Editors(2011) Quick Resume & Cover Letter Book: Write and Use an Effective Resume in Just One Day. Saint Paul, Minnesota. Jist Works Daniel Flage Ph.D(2003) The Art of Questioning: An Introduction to Critical Thinking. London. Pearson FACE(2016) Aptipedia Aptitude Encyclopedia. Delhi. Wiley publications 					
	tion: FAT, Assignments, Projects, Case studies, Role plays,					
3 Assessments wi	ith Term End FAT (Computer Based Test)					



Course Title	Course Title		L	T	P	J	C
ECE6099	Masters Thesis		0	0	0	0	16
Pre-requisite	As per the academic regulations	Syllabus version			ion		
		1.0					

To provide sufficient hands-on learning experience related to the design, development and analysis of suitable product / process so as to enhance the technical skill sets in the chosen field.

Expected Course Outcome:

At the end of the course the student will be able to

- 1. Formulate specific problem statements for ill-defined real life problems with reasonable assumptions and constraints.
- 2. Perform literature search and / or patent search in the area of interest.
- 3. Conduct experiments / Design and Analysis / solution iterations and document the results.
- 4. Perform error analysis / benchmarking / costing
- 5. Synthesise the results and arrive at scientific conclusions / products / solution
- 6. Document the results in the form of technical report / presentation

Contents

Capstone Project may be a theoretical analysis, modeling & simulation, experimentation & analysis, prototype design, fabrication of new equipment, correlation and analysis of data, software development, applied research and any other related activities.

Project should be for two semesters based on the completion of required number of credits as per the academic regulations.

Should be individual project.

In case of group projects, the individual project report of each student should specify the individual's contribution to the group project.

Carried out inside or outside the university, in any relevant industry or research institution.

Publications in the peer reviewed journals / International Conferences will be an added advantage

Mode of Evaluation: Periodic rev	iews, Presentat	ion, Final	oral viva, Poster submission
Recommended by Board of	10-06-2015		
Studies			
Approved by Academic Council	No. 37	Date	16-06-2015

Course Code	Course Title	L	T	P	J	C
ECE5031	QUANTUM PHYSICS FOR NANOSTRUCTURES	2	0	0	0	2
Pre-requisite	Nil					
Course Objecti	ve:					
The course is air						
1. Educate	various concepts of quantum theory and its importance.					
	em understand the different quantum nanostructures and their der	nsity	of s	tate	s.	
	nem to apply quantum theory to design nanoscale devices.					
Expected Cour	se Outcomes:					
Students will be						
1. Gain the	advanced concepts of quantum theory.					
	and the importance of Schrodinger wave equation & its application	ns.				
Obtain th	ne knowledge on quantum confinement effects.					
4. Gain the	knowledge in dispersion relation of electron in solids.					
5. Understa	and the quantum nanostructures, such as quantum dots, nanow	ires	and	qu	ant	un
wells and	d their density of states.					
6. Understa	and the time-dependent perturbation and its applications.					
Module:1 Int	roduction		4	ho	urs	
Importance of Q	uantum theory, Wave-particles duality, de-Broglie and Fermi W	avel	engt	hs,	Wa	ìV
function, Dynai	nical operators, Uncertainty principle, Quantum numbers and	l Hy	drog	gen	ate	on
problem, Pauli e	exclusion principle.					
M. J. J. 2 C.1		1		1		
	hrodinger equations and their formulation	1		ho	urs	
Schrodinger tim	e dependent and time independent wave equations - analytical so	lutio	ons.			_

Tunneling, Reflectance, transmittance and tunnelling probability, Scanning tunnelling microscope

Theory of conduction in solids 4 hours

Description of the theory of Conduction in Solids -Drude model, Nearly free electron model, Dispersion relation for electron.

Module:5 | Electronic Band Structure 5 hours

Periodic lattice, Brillouine zones, Periodic potential, Bloch Theorem, Kronig-Penny Potential and Electronic energy bands, direct and indirect gap semiconductors.

Quantum Confinement and Density of States 4 hours Module:6 Concept of Quantum Confinement, Quantum Dots, Quantum Well and Quantum Wires, Density

of states in 3D, 2D, 1D and 0D solid, carrier concentration.

Module://	Time	e-dep	end	lent pertur	bation and a	applicatio	ns			4 h	ours
Time-depen	dent cl	hange	in	potential, F	First-order tin	ne-depend	lent pert	urbati	on, Fer	mi's gold	en rule,
Photon em	ission	due	to	electronic	transitions,	Fermi's	golden	rule	for st	imulated	optical
transitions,	transitions, Semiconductor laser.										

Module:8 Contemporary issues: 2 hours	= 110 data 0 data 1 data	Module:8	Contemporary issues:	2 hours
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				Total Le	cture:	30 hours	
Tex	at Book(s)				1		
1	A. F. J. Levi, Applied (2006.	Quantum	n Mechanics, Secon	nd edition, Cambr	idge Un	iversity Press,	
2	Richard L. Liboff, Introd India, 2003.	luctory (Quantum Mechanics	s, Fourth edition, I	Pearson	Education Inc,	
Ref	Reference Books						
1	Robert Eisberg and Robert Resnick, Quantum Physics of Atoms, Molecules, Solids, Nuclei, and Particles, second Edition, John Wiley & Sons, Canada, 1985.						
2	A. Ghatak and S. Lokanathan, Quantum Mechanics—Theory & Applications, Macmillan India Limited, New Delhi, 2002.						
3	A. Beiser, Concepts of Modern Physics, Sixth edition, TataMcGraw- Hill Edition, New Delhi, 2003.						
(CA	Mode of Evaluation: Continuous Assessment Test –I (CAT-I), Continuous Assessment Test –II (CAT-II), Seminar / Challenging Assignments / Completion of MOOC / QUIZ, Final Assessment Test (FAT).						
Rec	commended by Board of St	tudies	13-12-2015				
App	proved by Academic Coun	cil	No. 40	Date	18-03-	2016	



Course Code	Course Title	L T P J C						
ECE5032	PHYSICS AND CHEMISTRY OF SOLIDS	2 0 0 0 2						
Pre-requisite Nil								
Course Objectives:								
The course is aimed to:								
classify	1. Provide understanding of properties of materials from an atomistic view point, and to classify solids.							
2. Outline	the properties and structure of crystalline materials, various mod	les of bonding in						

solids with appropriate examples.

3. Render them about thermodynamics and statistical mechanics of solids.

Expected Course Outcomes:

Students will be able to:

- 1. Gain knowledge on crystal structure
- 2. Understand various types of atomic bonding in solids.
- 3. Classify the materials based on their properties.
- 4. Identify different imperfections in solids.
- 5. Understand thermodynamics and elementary statistical mechanics.
- 6. Apply Magnetic, Optical & Thermal properties of different material for potential applications.

Module 1 | **Structure of Matter**

6 hours

Crystal structure & Bonding- Crystals, Polycrystals, Symmetry, Unit cells, Bravais lattices, Crystallographic directions, Crystallographic planes, Miller indices, Bragg's law, Single crystal and Powder X-ray diffraction.

Module 2 | Chemical Bonding

3 hours

Atomic Bonding in solids - Types of bond: Metallic, Ionic, Covalent and van der Waals bond; Hybridization; H-bonding Molecular orbital theory for simple molecules such as diatomic molecule etc.

Module 3 | Classification of Materials

2 hours

Different types of materials -Metals, Semiconductors, Composite materials, Ceramics, Alloys, and Polymers.

Module 4 | **Imperfections in solids**

2 hours

Imperfections of crystal structure –point defects, Grain boundaries, phase boundaries, Dislocations Screw, Edge and Mixed Dislocations

Module 5 Introduction to Thermodynamics and Elementary Statistical Mechanics

6 hours

The first and second laws of thermodynamics, Thermodynamic functions, enthalpy, entropy and Microstates, Introduction to Ionic Conductivity, Gibb's freeenergy, Gibb'sparadox, Liouville's theorem, Classical Statistical systems, Boltzman statistics, quantum statistical systems, Fermi-Diracand Bose-Einstein Statistics and their applications.

Module 6 | **Phase Transformations**

4 hours

Mechanisms of phase transformation; homogeneous and heterogeneous nucleation; spinodal



decompositi	on; order-disorder transfo	ormations; Martensit	ic transformation		
Module 7	Magnetic, Optical & T	hermal properties o	f solid		5 hours
Magnetic pi	roperties- Different kind	of magnetism in na	ture: Dia, Para, F	erro, A	Antiferro, Ferri,
Superpara;	Optical Properties-	Photoconductivity,	Opticalabsorptio	n &	transmission,
	escence, Fluorescence, P	•			-
Concept of p	phonon, Thermal conduct	ivity, Specific heat, E	Exothermic & endo	othermi	c processes.
Module 8	Contemporary issues:				2 hours
			Total Lec	ture:	30 hours
Text Book(s	s)				
1 Charles	Kittel, Introduction to So	olid State Physics, 20	12, eighth Edition,	John V	Wiley & Sons
	ch and H. Löth, Solid-Stat	te Physics: An Introd	uction to Principle	s of Ma	aterial Science
	ourth edition, Springer				
Reference I					
	ekker, Macmillan, Solid S				
_	an Vlack, Elements of ma				
	Peter, Paula Julio, Physic	Ţ	•		
	ng, Chapman and Hall, In				
	n Elliott & S. R. Elliott,	The Physics and Ch	emistry of Solids,	, John	Wiley & Sons,
1998.					
	aluation: Continuous Ass	•	* *		
,	eminar / Challenging Ass	ignments / Completic	on of MOOC / QU	IZ, Fin	al Assessment
Test (FAT).		T			
	led by Board of Studies	13-12-2015	1		
Approved by	y Academic Council	No. 40	Date	18-03	-2016



	Vellore Institute of Technology (Deemed to be University under section 3 of UGC Act, 1956)					
Course Code	Course Title	L	T	PJ	C	
ECE5033	SYNTHESIS OF NANOMATERIALS AND THIN FILM 2 0 2 4 DEPOSITION					
Pre-requisite	Nil	I				
Course Objective	/es:					
	m understand the fabrication of nanostructures for advanced device and train the students about nanomaterial synthesis and thin fil		epo	ositic	on	
Expected Cours	e Outcomes::					
 Identify a synthesis Understand Know van Acquire In Learn the 	course students will be able to and understand various top-down and bottom-up approaches for national and apply vacuum technology for nanomaterial synthesis. The rious deposition techniques at the atomic and molecular level. Strowledge about structure and properties of thin films. The advanced concepts in various vapour deposition techniques. The earn deposit nanomaterials by various methods.	nom	iate	rial		
	nomaterial Synthesis - Top-Down Approach			our		
•	s- Inert gas condensation, aerosol method, Arc discharge, RF-plasmablation, Gas-phase synthesis, Spray Pyrolysis, Ball Milling, Comb				arc	
Module 2 Nar	nomaterial Synthesis - Bottom-up approach		6 ł	our	S	
Nucleation theor	ods - Zero dimensional, one dimensional and two dimensional y, Homogeneous and heterogeneous nucleation, Metal nanocrysta drothermal synthesis, Photochemical synthesis, Electrochem	ıls b	y re	educ	tion,	

Thermolysis routes, Sonochemical routes, Hybrid methods, Sol- gel, Micelles and microemulsions, Bio-Synthesis.

Module 3 Vacuum technology

3 hours

Concept of different vacuum pumps - rotary, diffusion, Turbo molecular pump, Cryogenic-pump, Ti-sublimation pump; Concept of different gauges - pirani, penning, Pressure control.

Module 4 | Wafer Growth and Epitaxial Deposition

3 hours

Crystal Growth - CZ, Float zone technique; Basic Properties of different substrates (e.g. semiconductor, glass); Wafer cutting; Sources and related effects of various contamination; Wafer processing; Epitaxial growth- Growth kinetics of epitaxy, Doping, Growth modes.

Module 5 | **Structure and properties of thin films**

4 hours

Definition of thin films- Environment (Gas phase and plasma) for thin film deposition, Deposition parameters and their effects on film growth; Physical parameters for evaluation of thin films-Surface roughness; Density; Stress in thin films; Adhesion; Stoichiometry.

т.	Module 6	DI .	•	• • • •) techniques
- 170		Physian	ITONOR	ANACITIAN	<i>.</i> •••	I toobnioiioc
- 11	,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,	FILVSICA	i vaimi i	1611012111011		// rec minimes

4 hours



Evaporation- Thermal evaporation, resistance evaporation, Electron beam evaporation, Ion vapor evaporation and Cathodic arc deposition; Molecular Beam Epitaxy; Sputtering- Glow discharge sputtering, Magnetron sputtering, Ion beam sputtering; Atomic layer deposition (ALD)-Importance of ALD technique.

Module 7 | Chemical vapor deposition techniques

4 hours

Fundamentals, Advantages and limitations of Chemical vapor deposition (CVD) techniques; Different kinds of CVD techniques- Metallorganic (MO) CVD, Photoassisted CVD, Thermally activated CVD, Plasma enhanced (RF, μ -Wave) CVD, Low pressure (LP) CVD, Atmospheric pressure (AP) CVD etc,.

Module 8 | Contemporary issues:

2 hours

Advanced Topics

Total Lecture:

30 hours

Text Book(s)

- 1. Guozhong Cao. Ed Nanostructures and Nanomaterials: Synthesis, Properties, and Applications, World Scientific Series in Nanoscience and Nanotechnology, 2011.
- 2. G.A. Ozin and A.C. Arsenault, Nanochemistry: A chemical approach to nanomaterials, Royal Society of Chemistry, 2009.

Reference Books

- 1. Bharat Bhushan, Handbook of Nanotechnology, Springer, 2005
- 2. Hari Singh Nalwa, Handbook Of Nanostructured Biomaterials And Their Applications In Nanobiotechnology, Journal of Nanoscience and Nanotechnology, 2005.
- 3. D.M. Hata, Introduction to Vacuum Technology, Prentice Hall New Jersey, 2007.
- 4. K. Jousten, Handbook of Vacuum Technology, John Wiley and sons, Weinheim, 2008.
- 5. S. Schmidt et.al., CFx thin films deposited by high power impulse magnetron sputtering: synthesis and characterization Surf.Coat.Technol. 2011, 206, pp. 646-653.
- 6. J. George, Preparation of Thin Films, Marcel Dekker, Inc., New York. 2005.

Mode of Evaluation: Continuous Assessment Test –I (CAT-I), Continuous Assessment Test –II (CAT-II), Seminar / Challenging Assignments / Completion of MOOC / QUIZ, Final Assessment Test (FAT).

Typical Projects

- 1. Green synthesis of nanoparticles and analysis using UV-Vis.
- 2. Kinetic analysis of growth of silver nanoparticles.
- 3. Demonstration of Electroless deposition process.
- 4. Growth of thin films by Electrodeposition technique.
- 5. Preparation and study of ferrofluids.
- 6. Hydrothermal synthesis of TiO2 nanoparticles and its optical study

Mode of Evaluation: Review I, II and III

List of Challenging Experiments (Indicative)

1.	Wet Chemical synthesis of Silver Quantum Dots - Effect of viscosity on the	6 hours
	growth and its characterization by UV-Visible spectroscopy.	
2.	Synthesis of ZnO nanoparticles by wet chemical route and its optical band	6 hours
	gap calculation.	
3.	Mie formalism of Optical absorption of Ag and Au nanoparticles for size	4 hours
	estimation.	



4.	Calculation of d-spacing and crys	stallite size of Nanor	naterials from X-1	ray	4 hours		
	diffraction data.						
5.	Thin film deposition using Electr	oplating technique a	and morphology		3 hours		
	characterization using Optical microscope.						
6.	6. Fabrication of thin films using Spin coating technique.				3 hours		
7.	7. Fabrication of metal thin films on silicon/glass substrate using Metal				4 hours		
			Total Laboratory	Hours	30 hours		
Mod	Mode of Evaluation: Continuous assessment of challenging experiments /Final Assessment Test						
(FA	(FAT).						
Rec	ommended by Board of Studies	13-12-2015			·		
App	Approved by Academic Council No. 40 Date 18-03-2016						



Course Code	Course Title	L	T	P	J
ECE5034	NANOMATERIAL CHARACTERIZATION	restand various Nanostructure characterization techniques. so on state-of-the-art metrology tools such as Scanning Probe optical spectroscopes. study the material's structure and properties that are probed and objects of metrological tools. sous morphological techniques and selecting appropriate tools for their various spectroscopic techniques. The Scanning probe techniques of characterisation. Optical and magnetic characterization techniques. The Scanning probe techniques with suitable techniques. The samples with sa			
Pre-requisite	Nil	•			
Course Objecti	ves:				
The course is air	med to:				
1. Make the	em understand various Nanostructure characterization techniques.				
	e students on state-of-the-art metrology tools such as Scanning Prol	be			
	opes and optical spectroscopes.				
	•	e	prob	ed	an
measure	d				
Expected Cour					
Students will be					
	ersant with conventional aspects of metrological tools.				
		ols	for	thei	ſ
future re					
	· · · · · · · · · · · · · · · · · · ·				
Module 1			4 h		
		am			
		CIII	auc	LII	ЛЗ
and Kandom En	ors, Statistical analysis of cirols.				
Module 2	Microscony Techniques		8 h		·C
		171			
Onfical micros	sopy, Election interoscopy seaming Election wheroscopy,	- H.I	1) X	W	
		E	DΧ,	W	
	ectron Microscopy; EELS; SPM.	E	DX,		
	ectron Microscopy; EELS; SPM.	E			DX
Transmission El Module 3	ectron Microscopy; EELS; SPM. Spectroscopy Techniques		9 h	our	DX s
Transmission El Module 3	Spectroscopy; EELS; SPM. Spectroscopy Techniques roscopy; Ellipsometer; XPS; XAS; XRD; Raman Spectroscopy		9 h	our	DX s
Module 3 UV-Vis Spectr	Spectroscopy; EELS; SPM. Spectroscopy Techniques roscopy; Ellipsometer; XPS; XAS; XRD; Raman Spectroscopy		9 h	our	DX s
Module 3 UV-Vis Spectr	Spectroscopy; EELS; SPM. Spectroscopy Techniques roscopy; Ellipsometer; XPS; XAS; XRD; Raman Spectroscopy		9 h	our Surf	DX s
Module 3 UV-Vis Spectrenhanced Rama Module 4	Spectroscopy; EELS; SPM. Spectroscopy Techniques roscopy; Ellipsometer; XPS; XAS; XRD; Raman Spectroscopy n Spectroscopy.	ру	9 h - \$	our Surf	DX s ace
Module 3 UV-Vis Spectrenhanced Rama Module 4 Basic design of	Spectroscopy Techniques roscopy; Ellipsometer; XPS; XAS; XRD; Raman Spectroscopy Scanning Tunneling Microscopy	py :: I	9 h - \$	our Surf	DX rs ace
Module 3 UV-Vis Spectre enhanced Rama Module 4 Basic design or operation, Quan	Spectroscopy Techniques Toscopy; Ellipsometer; XPS; XAS; XRD; Raman Spectroscopy In Spectroscopy. Scanning Tunneling Microscopy If Scanning Probe Microscopes; Scanning Tunneling Microscope	py :: I	9 h - \$	our Surf	DX rs ace
Module 3 UV-Vis Spectre enhanced Rama Module 4 Basic design or operation, Quan	Spectroscopy Techniques oscopy; Ellipsometer; XPS; XAS; XRD; Raman Spectroscop n Spectroscopy. Scanning Tunneling Microscopy f Scanning Probe Microscopes; Scanning Tunneling Microscope tum Mechanical Tunneling phenomenon in STM, Different mode	py :: I	9 h - \$	our Surf	DX rs ace
Module 3 UV-Vis Spectrenhanced Rama Module 4 Basic design or operation, Quant STS - Principles Module 5	Spectroscopy Techniques Toscopy; Ellipsometer; XPS; XAS; XRD; Raman Spectroscopy Scanning Tunneling Microscopy Scanning Probe Microscopes; Scanning Tunneling Microscope tum Mechanical Tunneling phenomenon in STM, Different modes of operation, applications. Atomic Force Microscopy	techniques. tanning Probe ties that are probed and s. trons s. t			
Module 3 UV-Vis Spectrenhanced Rama Module 4 Basic design or operation, Quant STS - Principles Module 5 Atomic Force I	Spectroscopy Techniques Toscopy; Ellipsometer; XPS; XAS; XRD; Raman Spectroscopy Scanning Tunneling Microscopy f Scanning Probe Microscopes; Scanning Tunneling Microscope tum Mechanical Tunneling phenomenon in STM, Different mode of operation, applications. Atomic Force Microscopy Microscope - Modes of operation of AFM, Advanced Modes of	py :: Fes c	9 h - 5 8 h Prince of op	our Surf our iple	es ace
Module 3 UV-Vis Spectrenhanced Rama Module 4 Basic design or operation, Quant STS - Principles Module 5 Atomic Force I	Spectroscopy Techniques Toscopy; Ellipsometer; XPS; XAS; XRD; Raman Spectroscopy Scanning Tunneling Microscopy Scanning Probe Microscopes; Scanning Tunneling Microscope tum Mechanical Tunneling phenomenon in STM, Different modes of operation, applications. Atomic Force Microscopy	py :: Fes c	9 h - 5 8 h Prince of op	our Surf our iple	es ace
Module 3 UV-Vis Spectrenhanced Rama Module 4 Basic design or operation, Quant STS - Principles Module 5 Atomic Force I Modulation, Co	Spectroscopy Techniques Toscopy; Ellipsometer; XPS; XAS; XRD; Raman Spectroscopy Scanning Tunneling Microscopy f Scanning Probe Microscopes; Scanning Tunneling Microscope tum Mechanical Tunneling phenomenon in STM, Different mode s of operation, applications. Atomic Force Microscopy Microscope - Modes of operation of AFM, Advanced Modes of nductive AFM, EFM, MFM, SCM.	py :: Fes c	9 h - \$ 8 h Prince of op 7 h FM	nour nour nour nour nour - F	es ace
Module 3 UV-Vis Spectrenhanced Rama Module 4 Basic design or operation, Quant STS - Principles Module 5 Atomic Force I Modulation, Co Module 6	Spectroscopy Techniques Toscopy; Ellipsometer; XPS; XAS; XRD; Raman Spectroscopy Scanning Tunneling Microscopy f Scanning Probe Microscopes; Scanning Tunneling Microscope tum Mechanical Tunneling phenomenon in STM, Different mode of operation, applications. Atomic Force Microscopy Microscope - Modes of operation of AFM, Advanced Modes of	py:: Hes o	9 h - \$ 8 h Prince of op 7 h FM	nour Surf nour iple erat	es ace

Principles, Components of SQUID systems, Vibrating Sample Magnetometer (VSM)

2 hours

Magnetic Characterization

Module 7



	dule 8 Contemporary issues:	2 hours
Ad	vanced Topics	
		45 11
Тот	Total	45 Hours
	xt Book(s) D.W. Cohn, E.M. Lifahitz, Consider Encyclopedia of Materials Characterize	vation. Advances
1.	R.W. Cahn, E.M. Lifshitz, Concise Encyclopedia of Materials Characteriz in Materials Sciences and Engineering, Elsevier, 2016.	
2.	Yang Leng, Materials Characterization: Introduction to Microscopic an Methods, John Wiley & Sons, 2013.	d Spectroscopic
Ref	ference Books	
1	Richard Leach, Fundamental Principles of Engineering Nanometrology, Els	sevier, 2014.
2	Mauro Sardela, Practical Materials Characterization, Springer, 2014.	
3	Ewen Smith, Geoffrey Dent, Modern Raman Spectroscopy: A Practical Wiley & Sons, 2013.	Approach, John
4	Nikodem Tomczak, Kuan Eng Johnson Goh, Scanning Probe Mic Scientific, 2011.	roscopy, World
5	Ernst Meyer, Hans J. Hug, Roland Bennewitz, Scanning Probe Microscop Tip,Springer Science & Business Media, 2013.	y: The Lab on a
6	Vladimir V. Tsukruk, Srikanth Singamaneni, Scanning Probe Microscopy Fundamentals and Practices, John Wiley & Sons, 2012.	of Soft Matter:
7	H. Weinstock, SQUID Sensors: Fundamentals, Fabrication and Applic	ations, Springer
8	Science & Business Media, 2012. Sam Zhang, Lin Li, Ashok Kumar, Materials Characterization Techniques,	CRC Press
Ü	2008.	Cite Tiess,
	de of Evaluation: Continuous Assessment Test –I (CAT-I), Continuous Asses	
	AT-II), Seminar / Challenging Assignments / Completion of MOOC / QUIZ, F	Final
	sessment Test (FAT).	
	t of challenging Experiments (Indicative)	4.1
1.	STS analysis of CNT.	4 hours
2.	Analysis of magnetic nanoparticle with MFM	4 hours
3.	Application of Electrostatic Force Microscopy.	3 hours
4.	Characterization of Graphene with optical microscope.	4 hours
5.	Measure the blood glucose with electrochemical workstation	3 hours
6.	Study the band gap of semiconductor nanoparticle using UV-Vis spectroscopy	3 hours
7.	Measure the band gap and structure of crystal with XRD.	3 hours
8.	Elemental analysis using EDAX	3 hours
9.	Study the property of graphene using Raman Spectroscopy.	3 hours
	Total Laboratory Hours	30 hours
	de of Evaluation: Continuous assessment of challenging experiments /Final A	ssessment Test
_ `	AT).	
	commended by Board of Studies 13-12-2015 proved by Academic Council No. 40 Date 18-	03-2016
Λþ	proved by reducinic Council 10.40 Date 10-	03-2010



Recommended by Board of Studies	13-12-2015		
Approved by Academic Council	No. 40	Date	18-03-2016



Course Code	Course Title	L	T	P	J	C
ECE6032	NANOELECTRONICS	2	0	2	4	4
Pre-requisite ECE5031- Quantum Physics for Nanostructures						
Course Object	ives:					
The course is a						
 Make th 	em understand various advanced concepts in nanoelectronics.					
2. Explore	the fundamentals on QED, SED, Molecular electronics and spintronics					
	e students on state-of-the-art computational tools for modelling and sim ctronics devices.	ulatio	on o	f		

Expected Course Outcomes:

Student will be able to

- 1. Gain the concepts of nanoelectronics such as ballistic transport and quantum confinement.
- 2. Understand various nanostructures and its applications towards Quantum Electronic Devices.
- 3. Acquire the fundamentals of Molecular Electronics
- 4. Obtain the knowledge of Single Electron Devices and carbon based nanoelectronic devices.
- 5. Learn the fundamentals of Spintronics.
- 6. Design and simulate various advanced nanoelectronic devices.

Module 1Introduction to Nanoelectronics3 hoursLimitations of the conventional MOSFETs at Nanoscales, MOSFET Scaling & implications,Introductory concepts of Ballistic transport and Quantum confinement, Differences in Few ElectronDevices (as analog version) and Single Electron Devices (as digital version) of Nanoelectronic devices

Module 2 Nanostructures and Quantum Electronic Devices 4 hours Low-dimensional structures- Quantum wells, Quantum wires and Quantum dots; Density of states in lowdimensional structures; Quantum Interference Devices; Split –Gate Transistor; Electron – Wave Transistor: Personant tunneling phenomena and its applications in diades and transistors

Transistor; Resonant tunneling phenomena and its applications in diodes and transistors. Module 3 Molecular Electronics 3 hours

Overview & Basics; Fabrication of molecular electronics-based transistor devices; Conductivity of organic polymers- Conduction mechanism in organic polymers; Polymer Electronics; Self-Assembling Circuits.

Module 4 Single Electron Devices 5 hours

Principle of operation- Single-Electron Effect, Coulomb Blockade Phenomenon; Theoretical Quantum Dot Transistor - Energy of Quantum Dot system, Single-Electron Quantum-Dot Transistor, Single transistors; Conductance Oscillation and Potential Fluctuation; Transport under Finite temperature and Finite Bias; Coulomb Blockade Devices.

Module 5 Carbon Nanoelectronics 4 hours

Carbon nanotubes - SWCNTs and MWCNTs; 1D quantization in nanotubes- van Hove singularities; Fabrication of CNTs; CNT FETs- Device characteristics, CNT-TUBFET, CNT-SET; and NanoWire FETs; Electronic structure of graphene; Graphene FETs- GNRFETs.

Module 6	Spintronics	2 hours



Func	lamentals o	of spintronics; Spintronic devices- spin diodes and spin transistors	
Mod	dule 7	Current Nanoelectronic Devices	7 hours
Quai	ntum Effec	ets in MOSFETs, Strained Silicon, Fully Depleted SOI-MOSFET, Double-G	ate MOSFET,
Mult	i-gate MC	SFETs, FIN-FET, Electrically Induced Junctions for EJ-MOSFETs, Ballis	stic Transport,
Cond	ductance Q	uantization, Quantum Point Contact Devices.	
Mod	lule 8	Contemporary issues:	2 hours
		Total Lecture Hours	30 hours
Text	Book(s)		
1.	Shunri O	da, David Ferry, Nanaoscale Silicon Devices, CRC Press, Taylor & Francis G	roup, 2015.
2.	K. Goser	, P. Glosekotter, Nanoelectronics and Nanosystems, Springer, 2005.	
Refe	rence Boo	ks	
1.	Suprio D	atta, Lessons from nanoelectronics, World Scientific publisher, 2015.	
2.	Karl Gos	er, Peter Glosekotter, Jan Dienstuhl, Nanoelectronics and Nanosystems-Fron	n Transistors
	to Moleci	ular and Quantum Devices, Springer-Verlag 2004.	
3.	C.N.R. R	ao and A. Govindaraj, Nanotubes and nanowires, RSC Publishing, 2005.	
4.	Konstant	in K. Likharev, Single Electron Devices and their Applications, IEEE proceed	ings, vol. 87,
	no. 4, Ap	ril 1999.p 606- 632.	
5.	Ziese and	M. J. Thornton Spin Electronics, Springer-Verlag, 2001.	
6.	Supriyo I	Datta, Quantum Transport-From Atom to Transistor, Cambridge University pr	ess, 2005.
Mod	e of Evalu	ation: Continuous Assessment Test –I (CAT-I) , Continuous Assessment Test	−II (CAT-II),

Typical Projects

1. Design a Double gate MOSFET with 10nm-16nm channel dimensions by referring a latest journal paper and analyze its performance through band diagram and electrical characteristics by make use of process and device simulators.

Seminar / Challenging Assignments / Completion of MOOC / QUIZ, Final Assessment Test (FAT).

- 2. Design a 2D SOI-MOSFET with 16nm technology node by referring a latest journal paper and analyze its performance through band diagram and electrical characteristics by make use of process and device simulators.
- 3. Design a gate around FINFET with 5nm fin length and 16nm channel length dimensions by referring a latest journal paper and analyze its performance through band diagram and electrical characteristics by make use of process and device simulators.
- 4. Solve relevant mathematical equations and plot band structure and DOS of various types of CNTs.
- 5. Solve relevant mathematical equations and plot band structure and DOS of various types of graphene nano ribbons(GNRs).
- 6. Solve NEGF equation for quantum transport of a 2D graphne FET and analyze its electrical characteristics.

Mode of Evaluation: Review I, II and III			
Recommended by Board of Studies	13-12-2015		
Approved by Academic Council	No. 40	Date	18-03-2016



Course Code	Course Title	L	T	P	J	C
ECE6033	NANOPHOTONICS	3	0	0	0	3
Pre-requisite	ECE5031 - Quantum Physics for nanostructures					

The course is aimed to:

- 1. Expose them to the emerging area of nanophotonics and the phenomena involved in such devices.
- 2. Provide deep understandings of light matter interaction at nanoscale.
- 3. Study different types of nanophotonic crystal based devices and systems.

Expected Course Outcomes:

At the end of course student will be able to

- 1. Gain the foundations of nanophotonics.
- 2. Understand the mathematical synthesis of Maxwell equations for Photonic systems.
- 3. Acquire the understanding and importance of confinement and propagation.
- 4. Obtain the knowledge of 1-D, 2-D and 3-D Photonic Crystals.
- 5. Gain the design and scope of nano-photonics applications.
- 6. Learn the foundation of plasmonics.

Module 1 | **Foundations of Photonics**

4 hours

Photons and Electrons - Similarities and differences, Light Interaction with Matter, Complex refractive index and dielectric constant, Dispersion in Materials.

Module 2 | **Maxwell equations for Photonic systems**

6 hours

Basic Maxwell equations and their interpretations, Master's Equation for dielectric medium and its analytical solution.

Module 3 | Confinement and Propagation

6 hours

Confinement of Photons and Electrons, Co-operative effects for Photons and Electrons, Propagation through Classically Forbidden Zone- Tunneling, Concept of Near-Field phenomena in Photonic Crystals and Evanescent wave.

Module 4 | **Photonic Crystals**

8 hours

1-D, 2-D and 3-D Photonic crystal, Theoretical and mathematical description of Photonic band gap, Features and fabrication of Photonic crystals.

Module 5 | **Applications of Photonics**

6 hours

TE/TM Mode, Optical fiber, filters, switching devices, Kerr effect devices; Super Lenses – Micro and Nano Lenses, Prisms and Meta-materials, Graphene photonics.

Module 6 | **Phosphor materials in Photonics**

7 hours

Flourescence, Phosphorescence, rare earth doped nanostructures, activator and sensitizer, energy transfer process, life time, down and up conversation, FRET.

Module 7 | **Plasmonics**

6 hours

Fundamentals, wave equations, surface plasmon-polaritons, Plasmonics in gold and silver nanomaterials



Mo	dule 8	Contemporary issues:			2 hours
				Total Lectur	re: 45 hours
Tex	xt Book(<u>s)</u>			
1.	Paras P	rasad, Nanophotonics, Wiley-In	nterscience, 2004.		
2.	John D	O. Joannopoulos, Steven G. Joh	hnson, Joshua N.	Winn, Robert D.	Meade, Photonic
	Crystal	s: Molding the Flow of Light, se	econd Edition, Prin	ceton University Pr	ress, 2008
Ref	ference l	Books			
1.	Motoic	hi Ohtsu, Kiyoshi Kobayashi,	Tadashi Kawazoe	e, Takashi Yatsui,	Makoto Naruse,
	Princip	les of Nanophotonics, CRC Pres	ss, Taylor & Franci	is Group, 2008.	
2.	Stefan	A. Maier, Plasmonics: Fundame	entals and Applicat	ions, Springer Scien	nce, 2007.
3.	J. R. L	akowicz, Principle of Fluoreso	cence Spectroscop	y, third Edition, K	luwer Academic
	Publish	er, Newyork, 2007			
Mo	de of Ev	aluation: Continuous Assessmen	nt Test –I (CAT-I)	, Continuous Asses	sment Test –II
(CA	AT-II), S	eminar / Challenging Assignme	nts / Completion of	f MOOC / QUIZ, F	inal Assessment
Tes	st (FAT).				
Rec	commen	ded by Board of Studies	13-12-2015		
Ap	proved b	y Academic Council	No. 40	Date	18-03-2016



Programme Electives

Course Code	Course Title	L	T	P	J	C
ECE5035	SEMICONDUCTOR DEVICE PHYSICS AND TECHNOLOGY	2	0	0	4	3
Pre-requisite	Nil					

Course Objectives:

The course is aimed to:

- 1. Make them understand the physics of semiconductor materials and devices.
- 2. Educate the working mechanism and design of optoelectronic devices.
- 3. Train them to solve bandgap models and design different semiconductor devices.

Expected Course Outcomes:

Students will be able to

- 1. Gain in-depth knowledge in semiconductor physics
- 2. Acquire knowledge of mathematical model of various device fabrication processes
- 3. Gain in-depth knowledge of formation and properties of PN junctions
- 4. Obtain the fundamentals of metal-semiconductor junctions
- 5. Gain the physics of optoelectronic devices
- 6. Understand the fabrication and characteristics of nanoscale MOSFETs
- 7. Apply the concepts and techniques to solve bandgap model equations and design various semiconductor devices.

Module 1 | **Semiconductor Physics**

6 hours

Energy Bands and Carrier Concentration in thermal Equilibrium: Semiconductor Materials, Basic Crystal Structure, Basic Crystal Growth Technique, Valence Bands, Energy Bands, Intrinsic Carrier Concentration, Donors and Acceptors. Carrier Transport Phenomena: Carrier Drift, Carrier Diffusion, Generation and Recombination Processes, Continuity Equation, Thermionic Emission Process, Tunneling Process, High-Field Effects.

Module 2 | **Device Process stages I**

3 hours

Device Process stages I: Mathematical models relevant to thermal diffusion and ion implantation and Annealing. Pattern transfer; Optical lithography, Photoresists, Alignment and exposure, Etching.

Module 3 | **Device Process stages II**

3 hours

Mathematical models relevant to Deposition; Physical and chemical vapor deposition, Epitaxy. Process Integration: Device isolation, contacts metallization.

Module 4 | P-N Junction

5 hours

Diode fabrication, Device physics: Thermal equilibrium, Internal electro-static fields and potentials, Poisson's equation, continuity equations, drift-diffusion equations. I-V Characteristics: Forward bias, reverse bias, Diode equation. Capacitive effect: Junction and diffusion capacitance. DC, AC and transient analysis of Diodes.

Module 5 | Metal-Semiconductor Contacts and Schottky Diodes

4 hours



Metal-Semiconductor Junction diode Fabrication, Device Physics: Ideal MS contacts, Schottky diode-Electrostatics, I-V characteristics, DC, AC and transient analysis. Metal-Semiconductor contacts: Ohmic contacts, Schottky contacts, Tunnel contacts and Annealed and alloyed contacts.

Module 6 | Optoelectronic Diodes

3 hours

Photodiode Fabrication, device Physics of pn Junction Photodiodes, p-i-n Photo diodes. Principle of operation and fabrication technologies of Solar cell, LED and LASER diodes.

Module 7 | MOSFET

4 hours

MOS capacitor, MOSFET device fabrication, MOSFET Physics: I-V characteristics, Subthreshold region, Body effect, Capacitive effect, small and large signal model. MOSFET Short Channel effects: Punch through, DIBL, Hot electron effect, Velocity Saturation, Leakage current. MESFETs and MODFET analysis.

Module 8 Contemporary issues:

2 hours

Advanced Topics

Total Lecture:

30 Hours

Text Books(s)

- 1. S. M. Sze and Ming-Kwei Lee, Semiconductor Devices Physics and technology, John Wiley & Sons, 2013.
- 2. Grundmann and Marius, Physics of Semiconductors, Springer, 2010

Reference Books

- 1. Ben G. Streetman and Sanjay Banerjee, Solid State Electronic Devices, Pearson Ed, 2014.
- 2. M. S. Tyagi, Introduction to semiconductor materials and devices, John Wiley & Sons, 2008.
- 3. Campbell, Stephan, Fabrication Engineering at the Micro and Nanoscale, Oxford University Press, 2008.
- 4. Robert F. Pierret, Semiconductor Device Fundamentals, Pearson Education, 2006.
- 5. Richard C. Jaeger, Introduction to Microelectronic Fabrication, Prentice Hall, 2001.

Mode of Evaluation: Flipped Class Room, [Lecture to be videotaped], Use of physical and computer models to lecture, Visit to Industry, Min of 2 lectures by industry experts

Typical Projects

- 1. Solve relevant mathematical equations and plot band structure then extract effective mass of direct and indirect bandgap semiconductors.
- 2. Solve drift-diffusion equation for transport parameters (Drift velocity, mobility and conductivity) of direct and indirect band gap materials.
- 3. Design a P-N junction diode with smallest dimensions by referring a latest journal paper and analyze its performance through band diagram and electrical characteristics.
- 4. Design a MOSFET with smallest dimensions by referring a latest journal paper and analyze its performance through band diagram and electrical characteristics by make use of process and device simulators.
- 5. Design a MOSFET with smallest dimensions by referring a latest journal paper and analyze its performance through band diagram and electrical characteristics by make use of process and device simulators.
- **6.** Design a LASER diode with smallest dimensions by referring a latest journal paper and analyze its performance through band diagram and electrical characteristics by make use of process and device simulators.

Mode of Evaluation: Review I, II and III



Course Code	Course Title	
ECE5036	MEMS To NEMS	2 0 0 4 3
Pre-requisite	None	

The course is aimed to:

- 1. Make them to understand the technology of MEMS and NEMS.
- 2. Expose them about fabrication processes for development of MEMS/NEMS devices and systems.
- 3. Educate about the potential applications of NEMS.

Expected Course Outcomes:

At the end of course students will be able to

- 1. Acquire the knowledge of mechanisms in MESM/NEMS
- 2. Understand various engineering mechanics of microsystems
- 3. Gain the concept in finite element analysis of microsystems
- 4. Obtain the knowledge of MEMS fabrication
- 5. Acquire knowledge of quantum effects in MEMS/NEMS
- 6. Apply the knowledge of system integration in MEMS/NEMS
- 7. Design and simulate micro/nano sensors and actuators.

Module 1 Introduction 2 hours

Overview of MEMS / NEMS and various devices, Scaling geometry, Rigid Body Dynamics, Forces, Electron transfer, Fluid mechanics and Heat transfer.

Module 2Engineering mechanics for Microsystems design4 hours

Static Bending of Thin plates, Mechanical vibration, Resonant vibration, Design theory of Accelerometers, and Thermal analysis, Thermal effects on Mechanical strength of Materials, Creep formation.

Module 3 | **Finite Element Analysis**

5 hours

Concept of FEA, Comparison with other methods, Formulation from the governing Differential equations, Formulation based on stationary total potential, 1-D and 2-D Finite Element Analysis, Examples.

Module 4 Overview of Micro - Scale fabrication

2 hours

Microsystem fabrication process-Lithography, Dry and wet etching, Thin film deposition-PVD,CVD,LIGA, Micromolding, Electro-deposition

Module 5 | **Ouantum effects**

6 hours

Casimir Force and its influence in MEMS and NEMS, control of casimir force, Nanotribology-experimental techniques for studying anotribology, phonic friction, electronic friction, static friction, frictional anisotropy, stick-slip dynamics

Module 6 NEMS 7 hours

Introduction to nanoscale engineering, theory and characteristics of NEMS, Design and simulation techniques of NEMS – molecular dynamics, Potential energy models, Integration algorithms Molecular and Nanostructure Dynamics, Molecular Wires and Molecular Circuits



Mo	dule 7	System Integration				2 hours
Syst	tem Inte	gration and reliability				
Mod	dule 8	Contemporary issues:				2 hours
Adv	anced T	opics				
				T	otal Lecture:	30 hours
Tex	t Books	. /				
1.	Tai-ran	Hsu, MEMS and microsystems of 2008	esign a	nd manufact	ure, Nanoscale	e Engineering,
2.	Sergey	Edward Lyshevski, MEMS and NEM	S: Syste	ems, Devices,	and Structures	, CRC, 2002
Ref	erence l					
1.		, Text Book of Finite Element Analy				
2.		Edward Lyshevski, Nano- and Micro				ress, 2000
3.		Bhushan, Handbook of Micro/Nano				
4.		us T. Leondes, MEMS/NEMS Handb				
		aluation: Continuous Assessment Tes				
,	* '	eminar / Challenging Assignments / C	completi	on of MOOC	/ QUIZ, Final	Assessment
	t (FAT). pical Pro	inata			<u> </u>	
		*				
		gn of capacitance based actuators.				
		y of scaling effects in a magnetic syst lation of peizo based cantilever bean				
		ecular dynamics simulation	18			
		elerometer design				
		gn of capacitance based actuators.				
	o. Do	5. or capacitance cases actuators.				
Mod	de of Ev	aluation: Review I, II and III				
Rec	ommen	led by Board of Studies 13-1	2-2015			
Apr	proved b	y Academic Council No. 4	10	Date	18-03-20	016



Course Code	Course Title	L	T	P	J	C
ECE5037	NANOSENSORS	3	0	0	0	3
Pre-requisite	Nil					

The course is aimed to:

- 1. Offer an overview of basic nanosensor technology with examples drawn from existing products and literatures.
- 2. Enable them to identify suitable nanosensors and nanodevices for various potential applications.
- 3. Make them acquainted with various types of nanosensors and its potential applications.

Expected Course Outcomes:

At the end of this course students will be able to

- 1. Identify and understand various micro and nano-sensors and their working.
- 2. Learn material's properties used for the fabrication of nanosensors.
- 3. Gain the fundamentals of packaging and characterization of nanosensors.
- 4. Aware of various types of mechanical, chemical and optical nano-sensing systems.
- 5. Use nanostructured materials for developing nanobiosensors.

Module 1 | Micro and nano-sensors

3 hours

Sensing principles, sensor types and classification – Mechanical, acoustic, magnetic, thermal, chemical, radiation; microsensors; sensors based on surface - acoustic wave devices, biosensor, microfluids

Module 2 | **Materials for Nanosensors**

8 hours

Shape and size Dependence of Properties at Nanoscale, Surface Energy of a Solid, Core/Shell-Structured Nanoparticles, Metallic Nanoparticles and Plasmons Optical Properties of Bulk Metals and Metallic Nanoparticles, Quantum Dots, Carbon Nanotubes, Inorganic Nanowires, Nanoporous Materials.

Module 3 | Packaging and characterization of sensors

4 hours

Design, fabrication and characterization, Method of packaging at dye level, zero level and first level.

Module 4 | **Mechanical Nanosensors**

8 hours

Mass sensing- Nanogram Mass Sensing by Quartz Crystal Microbalance, MEMS/NEMS Resonators; Displacement sensor- Electron Tunneling Displacement Nanosensor, Coulomb Blockade Electrometer-Based Displacement Nanosensor, Nanometer-Scale Displacement Sensing by Single-Electron Transistor, Magnetomotive Displacement Nanosensor, Piezoresistive and Piezoelectric Displacement Nanosensors, Optical Displacement Nanosensor; Femtonewton Force Sensors- Doubly Clamped Suspended Carbon Nanotube Resonators, Suspended CNT Electromechanical Sensors for Displacement Membrane-Based and Force, **CNT Electromechanical Pressure Sensor**

Module 5 | Chemical Nanosensors

8 hours

Gas Sensors Based on Metallic Nanoparticles, Metal Oxides, Carbon Nanotube, Porous Silicon; Thin Organic Polymer Film–Based Gas Sensors; Electrospun Polymer Nanofibers as Humidity Sensors; Nanoelectronic Nose; CNT, Nanowire, and Nanobelt-Based Chemical Nanosensors



Module 6 Optical Nanosensors	6 hours
Noble-Metal Nanoparticles with LSPR and UV-Visible Spectroscopy, Nanoser	isors Based on
Surface-Enhanced Raman Scattering, Colloidal SPR Colorimetric Gold	
Spectrophotometric Sensor, Fiber-Optic Nanosensors, Nanograting-Based Optical	Accelerometer.
Module 7 Nanobiosensors	6 hours
Nanoparticle-Based Electrochemical Biosensors, CNT-Based Electrochemic	al Biosensors,
Functionalization of CNTs for Biosensor, Quantum Dot-Based Electrochemic	cal Biosensors,
Nanotube- and Nanowire-Based FET Nanobiosensors, Cantilever-Based Nanobios	ensors, Optical
Nanobiosensors, Biochips	
Module 8 Contemporary issues:	2 hours
Advanced Topics	
	T
Total Lecture:	45 hours
Text Book(s)	
1. Peter Hauptmann and Tim Pownall, Sensors: Principles and Applications, Pren	ntice Hall,
2003	
2. Vinod Kumar Khanna, Nanosensors: Physical, Chemical, and Biological, CRC	, 2012
Reference Books	
1. Kevin C. Honeychurch, Nanosensors for Chemical and Biological Applications	s: Sensing with
Nanotubes, Nanowires and Nanoparticles, woodhead publishing, 2014	
2. Teik-Cheng Lim, Nanosensors: Theory and Applications in Industry, Healthcar	re and Defense,
CRC, 2011	
Mode of Evaluation: Continuous Assessment Test –I (CAT-I), Continuous Assessment	
(CAT-II), Seminar / Challenging Assignments / Completion of MOOC / QUIZ, Fin	al Assessment
Test (FAT).	
` '	
Recommended by Board of Studies 13-12-2015	



Course Code	Course Title	L T P J C
ECE5038	CARBON NANOMATERIALS	3 0 0 0 3
Pre-requisite	Nil	

The course is aimed to:

- 1. Make the students understand the importance of carbon based nanostructured materials.
- 2. Study various carbon allotropes, their types, structure, properties and applications.
- 3. Emphasize other carbon based nanostructured materials such as nanocones, nanofibers, nanodiscs and nanodiamonds.

Expected Course Outcomes:

At the end of course, students will be able to:

- 1. Understand the importance of carbon based nanomaterials.
- 2. Obtain the knowledge on synthesis, characterization and application of various carbon based nanomaterials such as fullerene, carbon nanotubes and graphene.
- 3. Understand the functionalization and applications of CNT & Graphene.
- 4. Gain knowledge in other carbon based nanomaterials such as nanocones, nanofibers, nanodiscs and nanodiamonds.

Module 1 | Carbon Nanomaterials

2 hours

Introduction to Carbon Nanomaterials, Carbon allotropes and their bonding between carbon atoms.

Module 2 Fullerene

6 hours

Structure, Synthesis, Functionalization of fullerenes, Applications – Solar Cells, Hydrogen storage, Bio-applications.

Module 3 | Carbon nanotubes

8 hours

Types; Structure; Properties- Electrical, Optical, Mechanical, Vibrational properties; Nanotube synthesis - carbon arc discharge, Laser ablation, Chemical Vapor Deposition, High-pressure CO process, Purification techniques of carbon nanotube.

Module 4 | Functionalization and Applications of CNTs

8 hours

Functionalization- Covalent, non-covalent, and biological; Applications - Energy storage: Batteries, Fuel Cells: H₂, Li storage, supercapacitors; Molecular electronics—Field emitting devices and Transistors, drug delivery, CNT based microscopy, Nanotube sensors.

Module 5 | Graphene

7 hours

Electronic band structure, Properties of Graphene: chemical, mechanical, electronic and thermal. Synthesis of Graphene – Exfoliation, Epitaxial, CVD, Hummer Method; Graphene Nanoribbon-synthesis.

Module 6 | Functionalization and Applications of Graphene

6 hours

Functionalization- Covalent, non-covalent Application of Graphene; Applications – Graphene MOSFET – Opening a Band gap, Spintronics, Solar cells, gas sensors, supercapacitors.



Mo	dule 7	Other Carbon based materia	ıls			6 hours
Caı	bon Nan	ocomposite, Nanocones, Nanof	ibers, Nanodis	es and Nanodiamo	onds.	
Mo	dule 8	Contemporary issues:				2 hours
				Total L	ecture:	45 Hours
Tex	kt Book(s)				
1.		J.F Harris, Carbon Nanotubedge University Press, 2011	e Science: Sy	ynthesis, Properti	es and	Applications,
2.		H. Warner, Franziska Schaffenentals and Emergent Application			chmatiuk,	, Graphene:
Ref	ference l	Books				
1.	Zhong 2006	Lin Wang, Nanowires and Na	nobelts- Mate	rials, Properties a	nd Devi	ces, Springer,
2.	Thoma	s Webbester, Carbon Nanotube	preparation as	nd properties, CR	C Press,	1997
3.	R Saite	, G Dresselhaus, M S Dresselha	aus, Physical P	roperties of Carbo	n Nanoti	ıbes, Imperial
		press, 2004				
4.		ogotsi, Volker Presser, Carbon		-		
5.		Rao and A Govindaraj, Nachnology series, 2011	anotubes and	Nanowires, RO	CS Nano	oscience and
6.		el J. O'Connell, Carbon Nanotub group, 2006.	es: Properties	and Applications,	CRC Ta	ylor and
7.	2012	l I. Katsnelson, Graphene: Carb				
8.		do Langa, Jean-Francois Nieren iing, 2007	garten, Fullere	nes: Principles and	d Applica	ntions , RSC
(CA		aluation: Continuous Assessment eminar / Challenging Assignme	,			
	, ,	ded by Board of Studies	13-12-2015			
Ap	proved b	y Academic Council	No. 40	Date	18-03-2	2016



Course Code	Course Title	L	T	P	J	C
ECE5039	LITHOGRAPHIC TECHNIQUES FOR DEVICE	2	0	0	Λ	2
	FABRICATION	3	U	V	U	3
Pre-requisite	Nil	•				
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The course is aimed to:

- 1. Make conversant with conventional aspects of lithography, techniques related and their resolution aspects.
- 2. Introduce various existing Lithography techniques.
- 3. Study the principles, process steps and system components of the various lithographic techniques.

Expected Course Outcomes:

At the end of course students will be able to:

- 1. Obtain the in-depth knowledge in optical and electron beam lithography techniques.
- 2. Understand the conventional aspects of lithography, techniques related and their resolution aspects of X-ray, Ion, SPM based and soft lithography.
- 3. Learn and understand the importance of plasmonics in lithography

Module 1 | Optical Lithography

9 hours

Process steps involved in the optical lithography; Types - Contact, proximity printing and Projection Printing; Resolution Enhancement techniques for projection systems; Deep Ultraviolet lithography; Extreme Ultraviolet lithography; Scanning Near Field Optical Lithography.

Module 2 | **Electron Beam Lithography**

8 hours

Interaction of the electrons with the substrate; Electron Lithography System components; Raster scans and Vector scans; Electron resists and processing technique; Application of Electron Beam Lithography.

Module 3 | X-ray Lithography

4 hours

X-ray lithography system components, Resolution enhancement, X-ray mask construction, X-ray sources, x-ray resists.

Module 4 | **Ion Lithography**

3 hours

Ion lithography system components; Focused Ion Beam Lithography; Masked Ion Beam Lithography; Ion Projection Lithography.

Module 5 | **Scanning Probe Lithography**

8 hours

Scratching Lithography; Anodic Oxidation- Mechanism of Nano-oxidation; Dip-Pen Nanolithography - Mechanism, DPN Types: Parallel DPN, Polymer DPN, Application of DPN; Nano-shaving.

Module 6 | **Soft Lithography**

5 hours

Micro-contact printing, Solvent-Assisted Micromoulding, Micromoulding in capillaries, Patterning SAMs.



Mo	dule 7	Plasmonic Nanolithography				6 hours
Pri	nciple o	f Plasmonic Lithography, Pl	asmonic Mas	k, Near-field Pl	asmonic	Lithography,
Pla	smonic (Contact Lithography, Plasmonic	direct write lit	hography.		
Mo	dule 8	Contemporary issues:				2 hours
					1	
				Total Le	ecture:	45 hours
	kt Book(
1.		dman, Nanolithography: The A		ting Nanoelectron	nic and	Nanophotonic
		s and Systems, Woodhead Publi				
2.	•	Cabrini, Satoshi Kawata, Nano	fabrication Ha	ndbook, CRC Pre	ss, 2012.	
	ference]					
1.		W. Smith, Kazuaki Suzuki,	Microlithograp	ohy: Science and	Techno	logy, Second
		, CRC Press, 2007.	· 70 1 ·	. 3.61		. 2005
2.		knall, Nanolithography and Patte				
3.		. Madou, Manufacturing Techn	niques for Mic	crofabrication and	Nanote	chnology, 3rd
1		, Vol II, CRC Press, 2011.	footswine Can	maan Caiamaa (- D	i	Madia 2007
<u>4.</u> 5.		. Jackson, Micro and Nanomanu				
3.		e A. Tseng, Tip-Based Nanof & Business Media, 2011.	abrication: Fu	ndamentals and A	Аррисан	ons, Springer
6.		sok T. Soh, Kathryn Wilder G	uarini Calvin	F Quata Scanni	ng Probe	Lithography
0.		er Science & Business Media, 20		1. Quate, Scallin	ing 11000	Limography,
Mo		valuation: Continuous Assessme		AT-I) Continuou	ıs Assess	ment Test _II
		eminar / Challenging Assignme				
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	`	ded by Board of Studies	13-12-2015			
		y Academic Council	No. 40	Date	18-03-2	2016



Course Code	Course Title	L	T	P	J	C
ECE5040	PLASMONICS	2	0	0	4	3
Pre-requisite	Nil					

The course is aimed to:

- 1. Give a clear idea of changes in optical properties of nanostructures.
- 2. Enable to understand the fundamentals about surface plasmon polariton and plasmonic waveguides.
- 3. Make acquainted with various types of Spectroscopy and sensing techniques based on plasmonics.

Expected Course Outcomes:

At the end of course students will be able to:

- 1. Acquire the knowledge on electromagnetics of metallic nanoparticles.
- 2. Understand the fundamentals of surface plasmon polariton, and LSPR.
- 3. Understand the excitation dynamics at nanoscale.
- 4. Learn about nanocomposites and its application in the field of optoelectronics.
- 5. Familiar with nanostructured molecular architectures.
- 6. Obtain the basics on Surface-Plasmon-Polariton-Based Sensors.
- 7. Apply surface plasmon polariton, and LSPR concepts for designing nanophotonic devices.

Module 1 | Electromagnetics of Metallic Nano-particles

5 hours

Metallic Nano-particles, Maxwell equation and Electromagnetic wave equation, dispersion of the free electron gas and volume plasmons, real metals and intraband transitions, Electromagentic field in metals, Local Field Enhancement, Sub-wavelength aperture plasmonics,

Module 2 | **Plasmonic waveguides**

4 hours

Elements for surface plasmon polariton propagation, surface plasmon polariton band gap structures, metal nanowires for high confinement guiding and focusing, localized modes, metal nanoparticle waveguides

Module 3 | Localized surface plasmons

4 hours

- Normal modes of sub-wavelength metal particles, Mie theory, Observations of particle plasmons, coupling between localized plasmons, void plasmons and metallic nanoshells

Module 4 | Nanocontrol of Excitation Dynamics

4 hours

Nanostructure and excited states. Rare earth doped nanostructures Up-converting nanophores. Photon avalanche. Quantum cutting. Site isolating nanoparticles, prism and grating coupling, near field excitation.

Module 5 | Nanocomposites

4 hours

Nanocomposites as photonic media. Nanocomposite waveguides. Random lasers. Local field enhancement. Multiphase nanocomposites. Nanocomposites for optoelectronics. Polymer dispersed liquid crystals. Nanocomposite metamaterials.

Module 6 Nanostructured Molecular Architectures

4 hours

Noncovalent interactions. Nanostructured polymeric media. Molecular machines. Dendrimers.



Sup	ramolec	ular structures. Monolayer a	and multi	layer molecular assemblies.	
Mod	dule 7	Spectroscopy and sensing			3 hours
				n-Polariton-Based Sensors, Me	
_	-	1 1 1		ect Lens, Imaging and Lithograph	
	,	<u></u>			<i>J</i>
Mod	dule 8	Contemporary issues:			2 hours
	Total Lecture:		30 hours		
Tex	t Book(s)			
1.	Stefan	Alexender Maier, Plasmonic	s – Funda	amental and Applications, Spring	er, 2007.
2.	Paras P	rasad, Nanophotonics, Wiley	y-Intersci	ience, 2004.	
Ref	erence l	Books			
1.		<u>-</u>		face Plasmon Nanophotonics, Spi	
2.				row, and Kurt Busch, Nanopho	otonic Materials:
		ic Crystals, Plasmonics, and			
3.				oduction to Metal–Nanoparticle	Plasmonics, A
		Science Wise Co–Publication	n, 2013		
		ects (Indicative)			
		eposition of plasmonic nanor			
		nemical investigation of hot		dynamics	
		ic simulations with light bear			
		spin Hall effect from single			
		on and optical characterisati			
				of Nobel metal nanoparticles	
Mod	de of Ev	aluation: Review I, II and III	<u> </u>		
Rec	ommen	led by Board of Studies	13-12-2	2015	

No. 40

Date

18-03-2016

Approved by Academic Council



Course Code	Course Title	L	T	P	J	С
ECE6031	NANOMAGNETISM- FUNDAMENTALS AND	3	0	0	0	3
	APPLICATIONS					
Pre-requisite	ECE5031- Quantum Physics for Nanostructures					

The course is aimed to:

- 1. Make them understand the fundamentals of nanomagnetism and their applications.
- 2. Study the magnetism at macro- and nanoscale and their potential effects.
- 3. Enable students to apply the concepts of magnetic nanomaterials in the field of energy storage, biomedicine and environmental applications.

Expected Course Outcomes:

At the end of course students will be able to:

- 1. Gain in-depth knowledge about the concepts of magnetism at macro and nanoscale.
- 2. Obtain the knowledge about magnetism of localized electrons on the atom.
- 3. Gain the fundamentals about ferromagnetism, antiferromagnetism and other magnetic order.
- 4. Identify and understand the concepts of micro- and nanoscale magnetism
- 5. Apply the concepts to the application of magnetic nanomaterials in the field of magnetic recording, energy storage, biomedicine and environmental applications.

Module 1 | **Magnetostatics**

3 hours

Introduction - History - Magnetism and hysteresis, Magnetic dipole moment, Magnetic fields, Maxwell's equations, Magnetostatic energy and forces.

Module 2 | **Magnetism of electrons**

8 hours

Orbital and spin moments, Magnetic field effects – Zeeman effect, Theory of electronic magnetism, Magnetism of electrons in solids

Module 3 | Magnetism of localized electrons on the atom

8 hours

The hydrogenic atom and angular momentum, The many-electron atom, Paramagnetism, Ions in solids; crystal-field interactions.

Module 4 | Ferromagnetism and Exchange

8 hours

Mean field theory, Exchange interactions, Band magnetism, Collective excitations, Anisotropy, Ferromagnetic phenomena

Module 5 | Antiferromagnetism and other magnetic order

4 hours

Molecular field theory of antiferromagnetism, Ferrimagnets, Frustration, Amorphous magnets, Spin glasses, Magnetic models

Module 6 | Micromagnetism and Nanoscale magnetism

7 hours

Micromagnetic energy, Domain theory, Reversal, Pinning and Nucleation, Characteristic length scales, Superparamagnetism, Thin films, Thin-film heterostructures, Wires and needles, Small particles, Bulk nanostructures, Novel methods for synthesis of magnetic nanoparticles, Magnetic interactions: a tool to modify the magnetic properties of materials based on nanoparticles.



Module 7	Application	ns of nanomagne	etism		5 hours
Magnetic s	storage and	recording, Mag	gnetic resonance	Imaging, Hyperther	mia, Ferrofluid,
Biosensors.					
Module 8	Contempor	ary issues			2 hours
	,				
				Total Lecture	e: 45 hours
					·
Text Book((s)				
1. J. M. D	. Coey, Magi	netism and Magn	etic Materials, Pear	son Education, 2010	
2. B. D. O	Cullity, C. D	. Graham, Introd	uction to Magnetic	Materials, John W	iley & Sons, Inc,
2009.					
Reference l	Books				
1. R. C. 0	D'Handley, N	Iodern Magnetic	Materials: Princip	les and Application	s, John Wiley &
Sons, I	nc, 2000.				
2. C Binn	s, Nanomagn	etism: Fundamer	ntals and Applicatio	ns, Elsevier, 2014.	
3. David J	Jiles, Introduc	ction to Magnetis	m and Magnetic M	aterials, Chapman ar	nd Hall, 1991.
Mode of Ev	aluation: Co	ntinuous Assessi	ment Test –I (CAT	-I) , Continuous Ass	sessment Test –II
(CAT-II), S	eminar / Cha	llenging Assignr	nents / Completion	of MOOC / QUIZ,	Final Assessment
Test (FAT).		2 2 0	-		
Recommend	ded by Board	of Studies	13-12-2015		
Approved b	y Academic (Council	No. 40	Date	18-03-2016



Course Code	Course Title	L	1		J	C	
ECE6034	Energy Technologies	3 0 0 0 Syllabus Version					
Pre-requisite	ECE5032	S	ylla	bus V	ersio	n	
				1.	1		
Course Objectives	·•						
	the students about various energy sources and the possible	ility c	of h	arvest	ing		
	n nanomaterials			idi (OS)	8		
Expected Course							
	e the students will be able to:						
	I the various renewable energy sources.						
	knowledge on different energy harvesting methods.						
-	thermodynamics and kinetics of fuel cell process with nano	omate	eria	ls.			
	d choose suitable nanomaterials and nanostructures for photo						
5. Distinguish	different types and performance of solar collectors.						
	knowledge of electrochemical energy storage systems.						
7. Understand	the process and design issues in magnetic energy storage s	ystem	ıs.				
	Energy Harvesting				2 hou	rs	
	s of Renewable energy sources; Energy Harvesting - So						
	r, Thermoelectric, Piezoelectric; Energy harvesting devices	and	app	olicatio	ons.		
Nanomaterials for e Module 2 E	nergy Conversion I	1					
	nergy Conversion 1						
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thermodynamics;	on Types and mechanism; Electrochemical ener Hydrogen Technology; Fuel Cells - fundamentals, c	classif	fica	versions,	on, Opei	rating	
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continuity of the continuity o	Types and mechanism; Electrochemical ener Hydrogen Technology; Fuel Cells - fundamentals, or gn considerations, thermodynamics and kinetics of fuel cell, Fuel cell applications. Nanomaterials as electrode materials, Fuel cell applications. Nanomaterials as electrode materials as electrode materials of the cell, Fuel cell applications. Nanomaterials as electrode materials for Conversion II The otovoltaic fundamentals, Solar cell technologies, Types generation solar cells, Inorganic, Organic and perovskite yesis of solar cells Materials for Active Layers, yeard degradation. Solar Fuels: Hydrogen and CO ₂ reduction mergy Conversion II The otovoltaic fundamentals, Solar cell technologies, Types generation solar cells Types and performance of solar collectors - Flat Parabolic, Compound Parabolic and Fresnel Solar Conce of Solar Collectors; Heat Transfer fluids. The otovoltaic fundamentals and performance of solar collectors - Flat Parabolic, Compound Parabolic and Fresnel Solar Conce of Solar Collectors; Heat Transfer fluids. The otovoltaic fundamentals and performance of solar collectors - Flat Parabolic, Compound Parabolic and Fresnel Solar Conce of Solar Collectors; Heat Transfer fluids. The otovoltaic fundamentals and performance of solar collectors - Flat Parabolic, Compound Parabolic and Fresnel Solar Conce of Solar Collectors; Heat Transfer fluids. The otovoltaic fundamentals of solar cell technologies, Types generation solar cells for parabolic and perovskite years, and perovskite years of solar cells for personal solar cells fundamentals and testing. The otovoltaic fundamentals and testing of Techniques for Energy Devices - I greening for Energy Devices - I greening for Energy Devices of Information for the otovoltaic fundamentals and Spray of the otovoltaic fundamentals and selectrodes for printing devices of Information for the otovoltaic fundamentals and Spray of the otovoltaic fundamentals and testing for Energy Devices of Information fundamentals and testing fundamentals and selectrodes for b	Plate of the coati	Dye ce r ce nno e, I pors, patter apa	e sensible s	7 hour tized, format tors, dary, sodium e-moles, Labolarcel	rating nance rs nalysi rs Lead nion bility	



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proce	essing for printed and flexible electronic devices.		
Modu	ule 8 Contemporary issues:		2 hours
Adva	nced Topics		
		Total Lecture:	45 hours
Text	Book(s)	<u>.</u>	
1	Chetan Singh Solanki, Solar Photovoltatics Fundame PHI Learning Private limited, 2015	_	
2	Ru-shiliu, Leizhang, Xueliang sun, Electrochemical tec conversion, Wiley publications, 2012	hnologies for energy	storage and
Refe	rence Books		
1.	Caye M. Drapcho, Nghiem Phu Nhuan and Terry H. McGraw-Hill Companies, 2008		-
2.	Viswanathan, B and M Aulice Scibioh, Fuel Cells Press, 2006	rinciples and Applica	tions, Universities
3.	Schaeffer, John, Real Goods Solar Living Sourcebook Energy Technologies and Sustainable Living, Gaiam, 2		de to Renewable
4.	Frank Kreith and D.Yogi Goswami, Handbook of En Energy, CRC Press, 2007	ergy Efficiency and l	Renewable
5.	John Twidell and Tony Weir, Renewable Energy Reso	ources, Taylor & Fran	cis, USA, 2015
6.	Suganuma Katsuaki, Introduction to Printed Electron	ics, Springer, 2014.	
7.	Wong, William S., Salleo, Alberto (Editors) Flexible Springer, U.S./India 2009 ISBN: 9781441944 2.	948 DOI: 10.1007/9	78-0-387-74363-9 —
8.	Guozhen Shen, Zhiyong Fan (Editor) - Flexible Elect World Scientific, U.S. 2016 ISBN: 9789814651981		_
Mode	e of Evaluation: Continuous Assessment Test I (CAT-I)	, Continuous Assessi	ment Test II
	Γ-II), Seminar / Challenging Assignments / Completion	of MOOC / QUIZ, F	inalAssessment
	(FAT).		
	mmended by Board of Studies: 14.09.2020		
Appr	roved by Academic Council: 59 ^m AC	Date 24.09.	2020



Course Code	Course Title	L	T	P	J	С
ECE6095	Quantum Computation and Communication Technologies	3	0	0	0	3
Prerequisite:		Syllabus Version				n
				1.0)	

- 1. To study the basic ideas of quantum informatics, as well as the physical laws and basic mathematical principles that distinguish quantum information from classical information.
- 2. To exploit these properties in the design of quantum circuits, quantum algorithms that solve certain problems faster than classical algorithms can.
- 3. To learn about the pioneering efforts to operate quantum computing hardware using novel quantum systems.
- 4. To study the quantum error-correcting codes that can be exploited to protect quantum information from decoherence and other potential sources of error. Also tounderstand about quantum key distribution mechanisms for secured communication.

Expected Course Outcomes:

The student should be able:

- 1. To know the fundamental concepts of quantum mechanics and the quantum information theory.
- 2. To work with quantum circuits and master the mathematical apparatus of quantum mechanics used in quantum computations.
- 3. To apply the most important quantum logic algorithms.
- 4. To know the various types of quantum computing hardware realization techniques.
- 5. To solve the problems associated with noise and decoherence.
- 6. To work with quantum error correcting codes and fault-tolerant computation.
- 7. To master the mathematical apparatus of quantum communication theory and the most important protocols for the transfer and processing of quantum information;

Module 1 Statistical aspects of quantum mechanics and Quantum entanglement 8 Hours

Introduction and overview on Quantum computation and Quantum information. Qubit, Qubit as a quantum unit of information, Bloch sphere representation of a Qubit, Pure and mixed states of quantum systems, Density matrix and its properties, Multi-Qubit systems, Inseparability of quantum systems, Reduced density matrix. Photon Polarization - equations revisited

Applications of polarization in Quantum Networks. Quantum entanglement- Schmidt decomposition, Bell states, Measurements and Einstein-Podolsky-Rosen (EPR) paradox and Bell inequalities.

Module 2 Quantum Gates, Quantum Circuits and Quantum 7 Hours Computation 7

Quantum Gates-Simple Quantum Gates, Walsh-Hadamard Transformation, Swap Gate and Fredkin Gate. Correspondence with classical logic gates-NOT Gate, XOR Gate, AND Gate and OR Gate. Universal Quantum Gates. Quantum circuits, summary of the quantum circuit model of computation. Distinctive features of quantum computations- No-cloning theorem, Superdense coding, Quantum teleportation, Experiments on quantum teleportation of a qubit, Quantum Parallelism.

Module 3 Quantum Algorithms	6 Hours
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Simple Quantum Algorithms-Deutsch Algorithm, Deutsch-Jozsa Algorithm and Bernstein-Vazirani Algorithm, Simon's algorithm. Quantum Fourier Transform (QFT)-Period finding, implementing QFT-3(qubits) and more. Eigenvalue algorithm, Shor's algorithm for integer factorization. Module 4 Physical Implementations of a Quantum Computer 6 Hours Vincenzo criteria, Physical realizations of a quantum computer using NMR (Nuclear Magnetic Resonance), Trapped-Ions, Neutral atoms, Josephson Junction and Quantum dots based qubit methods. Other implementation schemes- Harmonic Oscillator, Optical Photon and Optical cavity quantum electrodynamics. Module 5 Quantum noise and Quantum Operations 4 Hours Decoherence- Open Quantum System, Measurements as Quantum operations, Examples of Quantum noise and Quantum Operations. Quantum Error Correcting Codes and Entropy Module 6 5 Hours Features of classical error correction theory, Classical three-bit code; Features of quantum error correction theory, Three-Qubit Bit-Flip code and Phase-Flip code-Bit-Flip QECC, Phase-Flip QECC; ine-Qubit Code. Fault-tolerant quantum computation. Entropy-Shannon Entropy, Von Neumann Entropy. Module 7 Quantum communication Theory 7 Hours Classical information over noisy quantum channel, Quantum information over noisy quantum channel, Entanglement as a Physical resource; Quantum cryptography- Private key cryptography, Privacy amplification and information reconciliation, Quantum Key Distribution (BB84 protocol), Eckert's Protocol for Quantum key distribution using entanglement. Privacy and coherent information and the security of Quantum Key Distribution. Module 8 Contemporary topics 2 Hours **Total Lecture:** 45 Hours # Mode: Flipped Class Room, [Lecture to be videotaped], Use of physical and computer models to lecture, Visit to Industry, Min of 2 lectures by industry experts Text Book(s) Nielsen, Michael A., and Isaac L. Chuang. Quantum Computation and Information. Cambridge, UK: Cambridge University Press,10th anniversary edition 2010.ISBN: 9780521635035. 2. John Watrous, The Theory of Quantum Information, Cambridge University Press, 2018. ISBN: 9781107180567; Mikio Nakahara, Tetsuo Ohmi. Quantum Computing: From Linear Algebra to Physical Realizations, CRC Press; 1st edition, 2008. ISBN-13: 978-0750309837 Reference Books Claude Cohen Tannoudji, Bernard Diu, Franck Laloë, Quantum Mechanics, Volume 1: Basic Concepts, Tools, and Applications, second edition, Wiley-VCH verlag, GmbH and Co,2019. J.J.Sakurai and Jim J.Napolitano, Modern Quantum Mechanics: Pearson IE, 2nd edition, 2 S. Loepp & W. K. Wooters, Protecting Information: From Classical Error Correction 3 to Quantum Cryptography, Cambridge Press, 2006 P Kaye, R Laflamme and M Mosca, An Introduction to Quantum Computing, Oxford University Press, 2007 Preskill, J. Notes on Quantum Computation. http://theory.caltech.edu/people/preskill/ph229/

Peres, Asher. Quantum Theory: Concepts and Methods. New York, NY: Springer,



Quantum Shannon theory Leat http://markwilde.com/teaching		, Mark M. Wilde	Notes are available
http://markwilde.com/teaching	g/		
	g/		
T1 M C 1 I A T			
Thomas M. Cover and Joy A. Thomas, Elements of Information theory, ISBN: 978-0-			
471-			
24195-9 July 2006			
Benenti G., Casati G, and Strini G., Principals of Quantum Computing and information,			
Vol I: Basic Concepts, Vol II: Basic tools and special topic, world scientific test			
FEvaluation: Continuous Assessi	ment Test, Qu	ıiz, Digital Assignm	ent, Final
nt Test.			
Recommended by Board of Studies: 14.09.2020			
Approved by Academic Council: 59 th AC Date 24.09.2020			24.09.2020
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Course Code	Course Title	L T P J C	
ECE6035	SPINTRONICS	2 0 0 4 3	
Pre-requisite ECE5031- Quantum Physics for Nanostructures			
011			
Course Object			
The course aime			
	te them understand the spin based electronics. By the magnetic materials, Spintronic based devices and fabrication.		
Expected Cou	<u>, , , , , , , , , , , , , , , , , , , </u>		
The student wil			
	the knowledge about Paramagnetism & diamagnetism.		
2. Acqu	uire the understanding and importance of Micromagnetics.		
	in the fundamental knowledge of Magnetic Materials		
	erstand the Electron Transport in Magnetic Systems		
	y properties of magnetic materials using advanced characterization to	ools and	
	niques.		
	in the design and scope of Spintronic Device fabrication Techniques ramagnetism & diamagnetism	2 hours	
	dered state, Itinerant-electron magnetism, Localized Magnetic System		
wagnetically of	dered state, fillerant-electron magnetism, Localized Magnetic System		
Module 2 Mi	cromagnetics	3 hours	
	ingle domain systems, Domain Walls, Exchange Bias and Magnetic		
	agnetic Materials	3 hours	
High-density re	cording materials, Soft Magnetic Materials (Ferrites), Magnetic Thin	Films, Dilute	
High-density re Magnetic semi	cording materials, Soft Magnetic Materials (Ferrites), Magnetic Thin conductors, Hemsler Alloys, SQUID Magnetometer, Highly S	Films, Dilute	
High-density re Magnetic semi	cording materials, Soft Magnetic Materials (Ferrites), Magnetic Thin	Films, Dilute	
High-density re Magnetic semi Systems, Molec	cording materials, Soft Magnetic Materials (Ferrites), Magnetic Thin conductors, Hemsler Alloys, SQUID Magnetometer, Highly Sule-based magnets, Single-molecule magnets.	n Films, Dilute pin Polarized	
High-density re Magnetic semi Systems, Molec Module 4 Ele	cording materials, Soft Magnetic Materials (Ferrites), Magnetic Thin conductors, Hemsler Alloys, SQUID Magnetometer, Highly S ule-based magnets, Single-molecule magnets. ectron Transport in Magnetic Systems	Films, Dilute pin Polarized 5 hours	
High-density re Magnetic semi Systems, Molec Module 4 Ele Degree of S	cording materials, Soft Magnetic Materials (Ferrites), Magnetic Thin conductors, Hemsler Alloys, SQUID Magnetometer, Highly Sule-based magnets, Single-molecule magnets. Sectron Transport in Magnetic Systems Spin Polarization, Idea of Tunneling, Magnetoresistance,	Films, Dilute pin Polarized 5 hours Anisotropic	
High-density re Magnetic semi Systems, Molec Module 4 Ele Degree of S	cording materials, Soft Magnetic Materials (Ferrites), Magnetic Thin conductors, Hemsler Alloys, SQUID Magnetometer, Highly S ule-based magnets, Single-molecule magnets. ectron Transport in Magnetic Systems	Films, Dilute pin Polarized 5 hours Anisotropic	
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High-density re Magnetic semi Systems, Molec Module 4 Ele Degree of S Magnetoresistan Module 5 Ch Magnetometry,	cording materials, Soft Magnetic Materials (Ferrites), Magnetic Thin conductors, Hemsler Alloys, SQUID Magnetometer, Highly Sule-based magnets, Single-molecule magnets. Extron Transport in Magnetic Systems Spin Polarization, Idea of Tunneling, Magnetoresistance, ace (AMR), Hall Effect (Planar & Anomalous) and Spin Polarized stansaracterization of Magnetic Materials	5 hours Anisotropic tes. 6 hours	
High-density re Magnetic semi Systems, Molec Module 4 Ele Degree of S Magnetoresistan Module 5 Ch Magnetometry,	cording materials, Soft Magnetic Materials (Ferrites), Magnetic Thin conductors, Hemsler Alloys, SQUID Magnetometer, Highly Sule-based magnets, Single-molecule magnets. Sectron Transport in Magnetic Systems Spin Polarization, Idea of Tunneling, Magnetoresistance, ace (AMR), Hall Effect (Planar & Anomalous) and Spin Polarized statement of Magnetic Materials SQUID, VSM, Torque, Faraday Balance, Kerr Effect, Magnetoresistance, Magnetoresistance, SQUID, VSM, Torque, Faraday Balance, Kerr Effect, Magnetoresistance, Magnetoresistance, SQUID, VSM, Torque, Faraday Balance, Kerr Effect, Magnetoresistance, Magnetoresistance, SQUID, VSM, Torque, Faraday Balance, Kerr Effect, Magnetoresistance, Magnetoresistance, Magnetoresistance, Magnetoresistance, SQUID, VSM, Torque, Faraday Balance, Kerr Effect, Magnetoresistance, Magnetores	5 hours Anisotropic tes. 6 hours	
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High-density re Magnetic semi Systems, Molect Module 4 Ele Degree of S Magnetoresistan Module 5 Ch Magnetometry, Microscopy, Sp Module 6 Sp Spintronics- O Magnetoresistan Magnetoresistan	cording materials, Soft Magnetic Materials (Ferrites), Magnetic Thin conductors, Hemsler Alloys, SQUID Magnetometer, Highly Sule-based magnets, Single-molecule magnets. Pectron Transport in Magnetic Systems Spin Polarization, Idea of Tunneling, Magnetoresistance, nce (AMR), Hall Effect (Planar & Anomalous) and Spin Polarized standaracterization of Magnetic Materials SQUID, VSM, Torque, Faraday Balance, Kerr Effect, Main Polarized STM. Intronic Devices rigins of Spin, Spin Mechanics, Origins of Spintronics, Spin nce, Giant Magnetoresistance (GMR), Colossal Magnetoresistance, Tunneling Magnetoresistance. Two-terminal devices-Spin valvence, Tunneling Magnetoresistance.	5 hours Anisotropic tes. 6 hours agnetic Force 6 hours current and nce, Ballistic yes, Tunneling	
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High-density re Magnetic semi Systems, Molect Module 4 Ele Degree of Magnetoresistan Module 5 Ch Magnetometry, Microscopy, Sp Module 6 Sp Spintronics- O Magnetoresistan Magnetoresistan MR devices, M Spin SET, and S Module 7 Sp	cording materials, Soft Magnetic Materials (Ferrites), Magnetic Thin conductors, Hemsler Alloys, SQUID Magnetometer, Highly Sule-based magnets, Single-molecule magnets. Extron Transport in Magnetic Systems Spin Polarization, Idea of Tunneling, Magnetoresistance, nee (AMR), Hall Effect (Planar & Anomalous) and Spin Polarized standaracterization of Magnetic Materials SQUID, VSM, Torque, Faraday Balance, Kerr Effect, Main Polarized STM. Intronic Devices Intronic Devices Intronic Magnetoresistance (GMR), Colossal Magnetoresistance, Tunneling Magnetoresistance. Two-terminal devices-Spin valva agnetic Field sensors, Read-Heads, MRAMS, Three-terminal Devices Spin LED. Intronic Device fabrication Techniques	5 hours Anisotropic tes. 6 hours agnetic Force 6 hours current and nce, Ballistic yes, Tunneling tes-Spin FET,	
High-density re Magnetic semi Systems, Molect Module 4 Ele Degree of S Magnetoresistan Module 5 Ch Magnetometry, Microscopy, Sp Module 6 Sp Spintronics- O Magnetoresistan Magnetoresistan Magnetoresistan Magnetoresistan MR devices, M Spin SET, and S Module 7 Sp Advanced devi	cording materials, Soft Magnetic Materials (Ferrites), Magnetic Thin conductors, Hemsler Alloys, SQUID Magnetometer, Highly Sule-based magnets, Single-molecule magnets. Extron Transport in Magnetic Systems Spin Polarization, Idea of Tunneling, Magnetoresistance, ace (AMR), Hall Effect (Planar & Anomalous) and Spin Polarized standaracterization of Magnetic Materials SQUID, VSM, Torque, Faraday Balance, Kerr Effect, Main Polarized STM. Intronic Devices rigins of Spin, Spin Mechanics, Origins of Spintronics, Spin ace, Giant Magnetoresistance (GMR), Colossal Magnetoresistance, Tunneling Magnetoresistance. Two-terminal devices-Spin valvagnetic Field sensors, Read- Heads, MRAMS, Three-terminal Devices Spin LED.	5 hours Anisotropic tes. 6 hours agnetic Force 6 hours current and nce, Ballistic yes, Tunneling tes-Spin FET,	
High-density re Magnetic semi Systems, Molect Module 4 Ele Degree of Magnetoresistan Module 5 Ch Magnetometry, Microscopy, Sp Module 6 Sp Spintronics- O Magnetoresistan Magnetoresistan MR devices, M Spin SET, and S Module 7 Sp	cording materials, Soft Magnetic Materials (Ferrites), Magnetic Thin conductors, Hemsler Alloys, SQUID Magnetometer, Highly Sule-based magnets, Single-molecule magnets. Extron Transport in Magnetic Systems Spin Polarization, Idea of Tunneling, Magnetoresistance, nee (AMR), Hall Effect (Planar & Anomalous) and Spin Polarized standaracterization of Magnetic Materials SQUID, VSM, Torque, Faraday Balance, Kerr Effect, Main Polarized STM. Intronic Devices Intronic Devices Intronic Magnetoresistance (GMR), Colossal Magnetoresistance, Tunneling Magnetoresistance. Two-terminal devices-Spin valva agnetic Field sensors, Read-Heads, MRAMS, Three-terminal Devices Spin LED. Intronic Device fabrication Techniques	5 hours Anisotropic tes. 6 hours agnetic Force 6 hours current and nce, Ballistic yes, Tunneling tes-Spin FET,	



				Total Lectur	re 30 hours
Text Book(s)					
1	, ,	Sakakima, and Inomata, Giant Ma	agneto-Resistive I	Devices, Springer V	erlag 2002.
2	D. Awschalom, D. Loss, and N.Samarth, Semiconductor Spintronics and Quantum				
		tation, Nano Science Technology	-		
Ref	erence l		, <u>F</u> 8, <u>-</u>		
1	Stefa 2006	n Visnovsky, Optics in Magnetic	Multi-layers and	l Nanostructures, C	CRC Publishers,
2	D.L. M	ills, J. A.C. Brand Nanomagnetisr	n, Elsevier Scienc	e and Technology,	2006.
3					, 2001.
4	Gerster	and Smith, The Physics and Cher	mistry of Material	s, Wiley, 2001.	
5	Buscho	w and De Boer, Physics of Magne	etism and Magneti	c Materials, Spring	er 2003.
6	R. L. C	arlin, Magnetochemistry, Springer	r-Verlag, Berlin, 1	986.	
7	U. N.Hartmann, Magnetic Multi-layers and Giant Magnetoresistance: Fundamentals and				
	Industrial Applications, Springer, 2000.				
8	M. Zies	se, M. J. Thornton Spin Electronic	s, Lecture Notes i	n Physics, Springer	, 2001.
		aluation: Continuous Assessment			
		eminar / Challenging Assignments	s / Completion of	MOOC / QUIZ, Fit	nal Assessment
Tes	t (FAT).				
~ 1	Typical Projects				
	1. Fabrication of magnetic tunnel junctions (MTJ) with MgO or AlO insulating barriers				
	2. Spin pumping and high frequency spin dynamics in MTJs				
	3. MTJ sensors for biological applications				
	4. Theory of spin-polarized transport and pure spin currents				
	5. Topological insulator-based spintronic devices.				
	Mode of Evaluation: Review I, II and III				
		led by Board of Studies	13-12-2015		
App	proved b	y Academic Council	No. 40	Date	18-03-2016



Course Code	Course Title	L T P J C
ECE6039	NANOELECTRONIC CIRCUIT DESIGN	3 0 0 0 3
Pre-requisite	ECE6032 - Nanoelectronics	
Course Objecti	ves:	

- To introduce students to the emerging design paradigms in various new nanotechnologies, for device and circuits.
- To bridge the existing gap between nanoelectronic device research and nanosystems design.

Expected Course Outcomes:

The student will be able to

- 1. Obtain the knowledge on advanced Nanoscale devices
- 2. Understand the operation and design FinFET based circuits.
- 3. Design reliable circuits using nanowire arrays and CNT interconnects.
- 4. Design logic circuits using quantum cellular automata.
- 5. Understand the design aspects of application specific Nanoscale ICs.
- 6. Model the circuits of Fin-FETs, CNT-FETs, GNR-FETs, RTDs and quantum dot devices using various SPICE versions.

Module 1Introduction to advanced nanoelectronic devices2 hoursNew device structures for next generation nanotechnology - carbon nanotube field-effect transistors (CNFETs), FinFETs, nanowire FETs, III/V compound-based devices, graphene nanoribbon devices, resonant tunneling diodes and quantum dot devices.2 hours

Module 2 | FinFET circuit and SRAM design

8 hours

Shorted-Gate and Independent-Gate FinFETs, Logic Design Using SG/IG-Mode FinFETs, Principle of TCMS, Logic Design Using TCMS, Latch Design Using SG/IG-Mode FinFETs, Precharge-Evaluate Logic Circuits, FinFET SRAM Design: Physics, Theory, and Modeling of FinFET Devices for SRAM Applications; Low-Power, High-Performance 90-nm DG-FinFET SRAM Design.

Module 3Reliable Circuits Design with Nanowire Arrays and CNT7 hoursInterconnects

Nanowire Fabrication Techniques, Crossbar Technologies, Architecture of Nanowire Crossbars, Decoder Logic Design. Emerging interconnect technologies: Study of Performances of Low-k Cu, CNTs, and Optical Interconnects; Local Interconnects: CNT Bundles Versus Cu and Global and Semi-global Interconnects.

Module 4 | Circuit Design with Quantum Cellular Automata

7 hours

QCA Fundamentals, Basic Logic Gates and Interconnect, Logic Design with QCA and Fabrication Technology and Challenges.

Module 5 | Nanoscale Application-Specific Integrated Circuits

6 hours

NASIC Building Blocks: Nanowires and xnwFETs, NASIC Circuit Styles, NASIC Logic Styles, NASIC Architectures and manufacturing methods.

Module 6	Circuit Design with Carbon Nanotube FETs & Resonant	8 hours
	Tunneling Diodes	



Mis-Positioned and Immune CNT Logic Design, Metallic-CNT-Immune CNFET Circuits.Metallic-CNT-Immune CNFET Circuits. Bistable Logic Using RTDs, Noise Margins of RTD-HBT Threshold Logic Gates, Monostable-Bistable Logic Elements and Circuit Examples for RTD-Based Devices.				
TOT KTD-B	Tor RTD-based Devices.			
Module 7	Circuit design with Graph	ene based Transist	tors	5 hours
Recent deve	elopments in Graphene Transi			GNRFET Digital
	nbipolar Logic Circuits.	,	, 0	
Module 8	Contemporary issues:			2 hours
Advanced 7				
			Total Lectur	re: 45 hours
Text Book	(\mathbf{s})			1
1. Niraj K	K. Jha and Deming Chen, Nan	oelectronic Circuit	Design, Springer pub	olications, 2011.
2. K. Gos				
Reference	Reference Books			
1. Yuan Taur and TakNing, Fundamentals of Modern VLSI Devices, Cambridge University Press, Newyark, 1998.				
3. Karl Goser, Peter Glosekotter, Jan Dienstuhl , Nanoelectronics and Nanosystems- From				
Transistors to Molecular and Quantum Devices, Springer-Verlag, 2004.				
4. John P. Uyemura, Introduction to VLSI Circuits and Systems, John Wiley & Sons, Inc, 2002.				
Mode of Evaluation: Continuous Assessment Test –I (CAT-I), Continuous Assessment Test –II				
(CAT-II), Seminar / Challenging Assignments / Completion of MOOC / QUIZ, Final Assessment				
Test (FAT).				
Recommended by Board of Studies 13-12-2015				
Approved by Academic Council No. 40 Date 18-03-2016				